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PSoC[®] 4: PSoC 4100 Family Datasheet

Programmable System-on-Chip (PSoC[®])

General Description

PSoC[®] 4 is a scalable and reconfigurable platform architecture for a family of mixed-signal programmable embedded system controllers with an Arm[®] Cortex[™]-M0 CPU. It combinesArm programmable and reconfigurable analog and digital blocks with flexible automatic routing. The PSoC 4100 product family, based on this platform, is a combination of a microcontroller with digital programmable logic, high-performance analog-to-digital conversion, opamps with Comparator mode, and standard communication and timing peripherals. The PSoC 4100 products will be fully upward compatible with members of the PSoC 4 platform for new applications and design needs. The programmable analog and digital sub-systems allow flexibility and in-field tuning of the design.

Features

32-bit MCU Sub-system

- 24-MHz Arm Cortex-M0 CPU with single-cycle multiply
- Up to 32 kB of flash with Read Accelerator
- Up to 4 kB of SRAM

Programmable Analog

- Two opamps with reconfigurable high-drive external and high-bandwidth internal drive and Comparator modes and ADC input buffering capability
- 12-bit 806 ksps SAR ADC with differential and single-ended modes and Channel Sequencer with signal averaging
- Two current DACs (IDACs) for general-purpose or capacitive sensing applications on any pin
- Two low-power comparators that operate in Deep Sleep

Low Power 1.71-V to 5.5-V operation

- 20-nA Stop Mode with GPIO pin wakeup
- Hibernate and Deep Sleep modes allow wakeup-time versus power trade-offs

Capacitive Sensing

- Cypress CapSense Sigma-Delta (CSD) provides best-in-class SNR (>5:1) and water tolerance
- Cypress supplied software component makes capacitive sensing design easy
- Automatic hardware tuning (SmartSense[™])

Segment LCD Drive

- LCD drive supported on all pins (common or segment)
- Operates in Deep Sleep mode with 4 bits per pin memory

Serial Communication

Two independent run-time reconfigurable serial communication blocks (SCBs) with reconfigurable I²C, SPI, or UART functionality

Timing and Pulse-Width Modulation

- Four 16-bit timer/counter pulse-width modulator (TCPWM) blocks
- Center-aligned, Edge, and Pseudo-random modes
- Comparator-based triggering of Kill signals for motor drive and other high reliability digital logic applications

Up to 36 Programmable GPIOs

- Any GPIO pin can be CapSense, LCD, analog, or digital
- Drive modes, strengths, and slew rates are programmable

Five different packages

- 48-pin TQFP, 44-pin TQFP, 40-pin QFN, 35-ball WLCSP, and 28-pin SSOP package
- 35-ball WLCSP package is shipped with I²C Bootloader in Flash

Extended Industrial Temperature Operation

■ -40 °C to + 105 °C operation

PSoC Creator Design Environment

- Integrated Development Environment provides schematic design entry and build (with analog and digital automatic routing)
- Applications Programming Interface (API Component) for all fixed-function and programmable peripherals

Industry Standard Tool Compatibility

After schematic entry, development can be done with Arm-based industry-standard development tools

198 Champion Court

San Jose, CA 95134-1709



More Information

Cypress provides a wealth of data at www.cypress.com to help you to select the right PSoC device for your design, and to help you to quickly and effectively integrate the device into your design. For a comprehensive list of resources, see the knowledge base article KBA86521, How to Design with PSoC 3, PSoC 4, and PSoC 5LP. Following is an abbreviated list for PSoC 4:

- Overview: PSoC Portfolio, PSoC Roadmap
- Product Selectors: PSoC 1, PSoC 3, PSoC 4, PSoC 5LP In addition, PSoC Creator includes a device selection tool.
- Application notes: Cypress offers a large number of PSoC application notes covering a broad range of topics, from basic to advanced level. Recommended application notes for getting started with PSoC 4 are:
 - □ AN79953: Getting Started With PSoC 4
 - □ AN88619: PSoC 4 Hardware Design Considerations
 - □ AN86439: Using PSoC 4 GPIO Pins
 - □ AN57821: Mixed Signal Circuit Board Layout
 - □ AN81623: Digital Design Best Practices
 - □ AN73854: Introduction To Bootloaders
 - □ AN89610: Arm Cortex Code Optimization
 - □ AN90071: CY8CMBRxxx CapSense Design Guide
 - □ AN85951: PSoC[®] 4 and PSoC 6 MCU CapSense[®] Design Guide

- Technical Reference Manual (TRM) is in two documents:
- □ Architecture TRM details each PSoC 4 functional block.
- □ Registers TRM describes each of the PSoC 4 registers.
- Development Kits:
 - CY8CKIT-042, PSoC 4 Pioneer Kit, is an easy-to-use and inexpensive development platform. This kit includes connectors for Arduino[™] compatible shields and Digilent® Pmod[™] daughter cards.
 - □ CY8CKIT-049 is a very low-cost prototyping platform. It is a low-cost alternative to sampling PSoC 4 devices.
 - CY8CKIT-001 is a common development platform for any one of the PSoC 1, PSoC 3, PSoC 4, or PSoC 5LP families of devices.

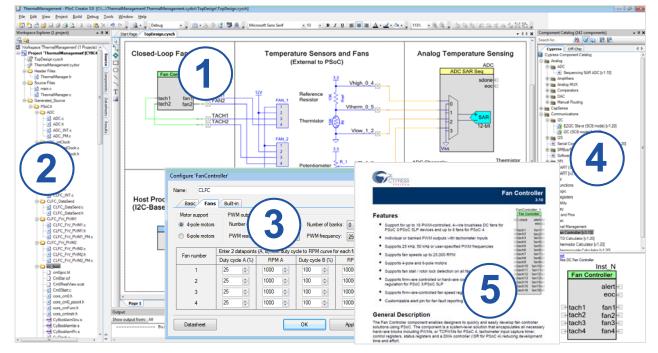
The MiniProg3 device provides an interface for flash programming and debug.

PSoC Creator

PSoC Creator is a free Windows-based Integrated Design Environment (IDE). It enables concurrent hardware and firmware design of PSoC 3, PSoC 4, and PSoC 5LP based systems. Create designs using classic, familiar schematic capture supported by over 100 pre-verified, production-ready PSoC Components; see the list of component datasheets. With PSoC Creator, you can:

- 1. Drag and drop component icons to build your hardware system design in the main design workspace
- Codesign your application firmware with the PSoC hardware, using the PSoC Creator IDE C compiler
- 3. Configure components using the configuration tools
- 4. Explore the library of 100+ components
- 5. Review component datasheets

Figure 1. Multiple-Sensor Example Project in PSoC Creator





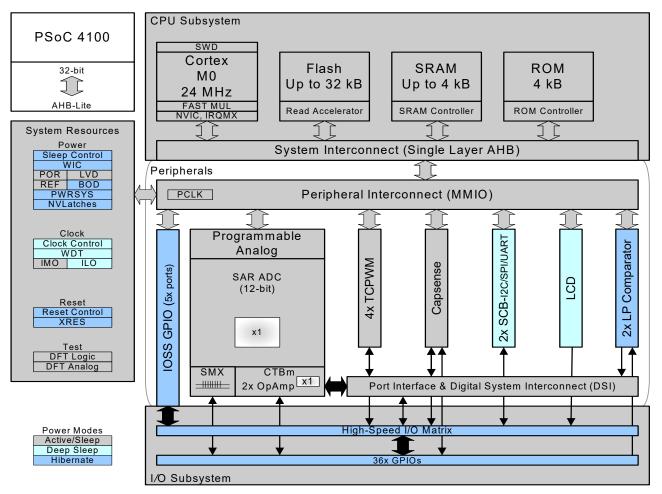
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Figure 2. Block Diagram



The PSoC 4100 devices include extensive support for programming, testing, debugging, and tracing both hardware and firmware.

The Arm Serial_Wire Debug (SWD) interface supports all programming and debug features of the device.

Complete debug-on-chip functionality enables full device debugging in the final system using the standard production device. It does not require special interfaces, debugging pods, simulators, or emulators. Only the standard programming connections are required to fully support debug.

The PSoC Creator Integrated Development Environment (IDE) provides fully integrated programming and debug support for the PSoC 4100 devices. The SWD interface is fully compatible with industry standard third party tools. With the ability to disable debug features, with very robust flash protection, and by allowing customer-proprietary functionality to be implemented in on-chip programmable blocks, the PSoC 4100 family provides a level of

security not possible with multi-chip application solutions or with microcontrollers.

The debug circuits are enabled by default and can only be disabled in firmware. If not enabled, the only way to re-enable them is to erase the entire device, clear flash protection, and reprogram the device with new firmware that enables debugging.

Additionally, all device interfaces can be permanently disabled (device security) for applications concerned about phishing attacks due to a maliciously reprogrammed device or attempts to defeat security by starting and interrupting flash programming sequences. Because all programming, debug, and test interfaces are disabled when maximum device security is enabled, PSoC 4100 with device security enabled may not be returned for failure analysis. This is a trade-off the PSoC 4100 allows the customer to make.



Functional Definition

CPU and Memory Subsystem

CPU

The Cortex-M0 CPU in PSoC 4100 is part of the 32-bit MCU subsystem, which is optimized for low power operation with extensive clock gating. It mostly uses 16-bit instructions and executes a subset of the Thumb-2 instruction set. This enables fully compatible binary upward migration of the code to higher performance processors such as the Cortex-M3 and M4, thus enabling upward compatibility. The Cypress implementation includes a hardware multiplier that provides a 32-bit result in one cycle. It includes a nested vectored interrupt controller (NVIC) block with 32 interrupt inputs and also includes a Wakeup Interrupt Controller (WIC), which can wake the processor up from Deep Sleep mode allowing power to be switched off to the main processor when the chip is in Deep Sleep mode. The Cortex-M0 CPU provides a Non-Maskable Interrupt input (NMI), which is made available to the user when it is not in use for system functions requested by the user.

The CPU also includes a debug interface, the serial wire debug (SWD) interface, which is a two-wire form of JTAG; the debug configuration used for PSoC 4100 has four break-point (address) comparators and two watchpoint (data) comparators.

Flash

PSoC 4100 has a flash module with a flash accelerator tightly coupled to the CPU to improve average access times from the flash block. The flash block is designed to deliver 0 wait-state (WS) access time at 24 MHz. Part of the flash module can be used to emulate EEPROM operation if required.

The PSoC 4200 Flash supports the following flash protection modes at the memory subsystem level:

- Open: No Protection. Factory default mode in which the product is shipped.
- Protected: User may change from Open to Protected. This mode disables Debug interface accesses. The mode can be set back to Open but only after completely erasing the Flash.
- Kill: User may change from Open to Kill. This mode disables all Debug accesses. The part cannot be erased externally, thus obviating the possibility of partial erasure by power interruption and potential malfunction and security leaks. This is an irrecvocable mode.

In addition, row-level Read/Write protection is also supported to prevent inadvertent Writes as well as selectively block Reads. Flash Read/Write/Erase operations are always available for internal code using system calls.

SRAM

SRAM memory is retained during Hibernate.

SROM

A supervisory ROM that contains boot and configuration routines is provided.

System Resources

Power System

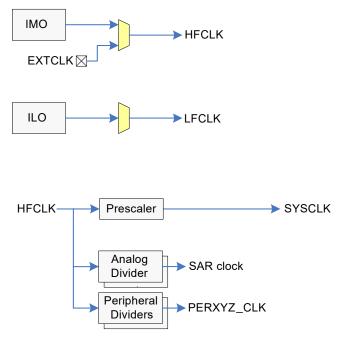
The power system is described in detail in the section Power on page 15. It provides assurance that voltage levels are as required for each respective mode and either delay mode entry (on power-on reset (POR), for example) until voltage levels are as required for proper function or generate resets (brown-out detect (BOD)) or interrupts (low-voltage detect (LVD)). The PSoC 4100 operates with a single external supply over the range of 1.71 V to 5.5 V and has five different power modes, transitions between which are managed by the power system. PSoC 4100 provides Sleep, Deep Sleep, Hibernate, and Stop low-power modes.

Clock System

The PSoC 4100 clock system is responsible for providing clocks to all subsystems that require clocks and for switching between different clock sources without glitching. In addition, the clock system ensures that no metastable conditions occur.

The clock system for PSoC 4100 consists of the internal main oscillator (IMO) and the internal low-power oscillator (ILO) and provision for an external clock.

Figure 3. PSoC 4100 MCU Clocking Architecture



The HFCLK signal can be divided down (see PSoC 4100 MCU Clocking Architecture) to generate synchronous clocks for the analog and digital peripherals. There are a total of 12 clock dividers for PSoC 4100, each with 16-bit divide capability. The analog clock leads the digital clocks to allow analog events to occur before digital clock-related noise is generated. The 16-bit capability allows a lot of flexibility in generating fine-grained frequency values and is fully supported in PSoC Creator.



IMO Clock Source

The IMO is the primary source of internal clocking in the PSoC 4100. It is trimmed during testing to achieve the specified accuracy. Trim values are stored in nonvolatile latches (NVL). Additional trim settings from flash can be used to compensate for changes. The IMO default frequency is 24 MHz and it can be adjusted between 3 MHz to 24 MHz in steps of 1 MHz. The IMO tolerance with Cypress-provided calibration settings is ±2%.

ILO Clock Source

The ILO is a very low power oscillator, which is primarily used to generate clocks for peripheral operation in Deep Sleep mode. ILO-driven counters can be calibrated to the IMO to improve accuracy. Cypress provides a software component, which does the calibration.

Watchdog Timer

A watchdog timer is implemented in the clock block running from the ILO; this allows watchdog operation during Deep Sleep and generates a watchdog reset if not serviced before the timeout occurs. The watchdog reset is recorded in the Reset Cause register.

Reset

PSoC 4100 can be reset from a variety of sources including a software reset. Reset events are asynchronous and guarantee reversion to a known state. The reset cause is recorded in a register, which is sticky through reset and allows software to determine the cause of the reset. An XRES pin is reserved for external reset to avoid complications with configuration and multiple pin functions during power-on or reconfiguration. The XRES pin has an internal pull-up resistor that is always enabled.

Voltage Reference

The PSoC 4100 reference system generates all internally required references. A 1% voltage reference spec is provided for the 12-bit ADC. To allow better signal to noise ratios (SNR) and better absolute accuracy, it is possible to bypass the internal reference using a GPIO pin or to use an external reference for the SAR.

Analog Blocks

12-bit SAR ADC

The 12-bit 806 ksps SAR ADC can operate at a maximum clock rate of 14.5 MHz and requires a minimum of 18 clocks at that frequency to do a 12-bit conversion.

The block functionality is augmented for the user by adding a reference buffer to it (trimmable to \pm 1%) and by providing the choice (for the PSoC 4100 case) of three internal voltage references: V_{DD}, V_{DD}/2, and V_{REF} (nominally 1.024 V) as well as an external reference through a GPIO pin. The sample-and-hold (S/H) aperture is programmable allowing the gain bandwidth requirements of the amplifier driving the SAR inputs, which determine its settling time, to be relaxed if required. System performance will be 65 dB for true 12-bit precision providing appropriate references are used and system noise levels permit. To improve performance in noisy conditions, it is possible to provide an external bypass (through a fixed pin location) for the internal reference amplifier.

The SAR is connected to a fixed set of pins through an 8-input sequencer. The sequencer cycles through selected channels autonomously (sequencer scan) and does so with zero switching overhead (that is, aggregate sampling bandwidth is equal to 806 ksps whether it is for a single channel or distributed over several channels). The sequencer switching is effected through a state machine or through firmware driven switching. A feature provided by the sequencer is buffering of each channel to reduce CPU interrupt service requirements. To accommodate signals with varying source impedance and frequency, it is possible to have different sample times programmable for each channel. Also, signal range specification through a pair of range registers (low and high range values) is implemented with a corresponding out-of-range interrupt if the digitized value exceeds the programmed range; this allows fast detection of out-of-range values without the necessity of having to wait for a sequencer scan to be completed and the CPU to read the values and check for out-of-range values in software.

The SAR is able to digitize the output of the on-board temperature sensor for calibration and other temperature-dependent functions. The SAR is not available in Deep Sleep and Hibernate modes as it requires a high-speed clock (up to 18 MHz). The SAR operating range is 1.71 V to 5.5 V.

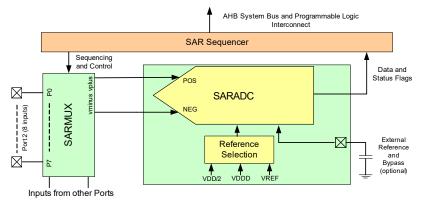


Figure 4. SAR ADC System Diagram



Two Opamps (CTBm Block)

PSoC 4100 has two opamps with Comparator modes which allow most common analog functions to be performed on-chip eliminating external components; PGAs, voltage buffers, filters, trans-impedance amplifiers, and other functions can be realized with external passives saving power, cost, and space. The on-chip opamps are designed with enough bandwidth to drive the S/H circuit of the ADC without requiring external buffering.

Temperature Sensor

PSoC 4100 has one on-chip temperature sensor This consists of a diode, which is biased by a current source that can be disabled to save power. The temperature sensor is connected to the ADC, which digitizes the reading and produces a temperature value using Cypress supplied software that includes calibration and linearization.

Low-power Comparators

PSoC 4100 has a pair of low-power comparators, which can also operate in the Deep Sleep and Hibernate modes. This allows the analog system blocks to be disabled while retaining the ability to monitor external voltage levels during low-power modes. The comparator outputs are normally synchronized to avoid metastability unless operating in an asynchronous power mode (Hibernate) where the system wake-up circuit is activated by a comparator switch event.

Fixed Function Digital

Timer/Counter/PWM Block (TCPWM)

The TCPWM block consists of four 16-bit counters with user-programmable period length. There is a Capture register to record the count value at the time of an event (which may be an I/O event), a period register which is used to either stop or auto-reload the counter when its count is equal to the period register, and compare registers to generate compare value signals which are used as PWM duty cycle outputs. The block also provides true and complementary outputs with programmable offset between them to allow use as deadband programmable complementary PWM outputs. It also has a Kill input to force outputs to a predetermined state; for example, this is used in motor drive systems when an overcurrent state is indicated and the PWMs driving the FETs need to be shut off immediately with no time for software intervention.

Serial Communication Blocks (SCB)

The PSoC 4100 has two SCBs, which can each implement an I^2 C, UART, or SPI interface.

I²C Mode: The hardware I²C block implements a full multi-master and slave interface (it is capable of multimaster arbitration). This block is capable of operating at speeds of up to 1 Mbps (Fast Mode Plus) and has flexible buffering options to reduce interrupt overhead and latency for the CPU. The FIFO mode is available in all channels and is very useful in the absence of DMA.

The I²C peripheral is compatible with the I²C Standard-mode, Fast-mode, and Fast-Mode Plus devices as defined in the NXP I²C-bus specification and user manual (UM10204). The I²C bus I/O is implemented with GPIO in open-drain modes. The I²C bus uses open-drain drivers for clock and data with pull-up resistors on the bus for clock and data connected to all nodes. The required Rise and Fall times for different I²C speeds are guaranteed by using appropriate pull-up resistor values depending on VDD, Bus Capacitance, and resistor tolerance. For detailed information on how to calculate the optimum pull-up resistor value for your design, refer to the UM10204 I2C bus specification and user manual (the latest revision is available at www.nxp.com).

PSoC 4100 is not completely compliant with the I^2C spec in the following respects:

- GPIO cells are not overvoltage-tolerant and, therefore, cannot be hot-swapped or powered up independently of the rest of the I²C system.
- Fast-mode Plus has an I_{OL} specification of 20 mA at a V_{OL} of 0.4 V. The GPIO cells can sink a maximum of 8-mA I_{OL} with a V_{OL} maximum of 0.6 V.
- Fast-mode and Fast-mode Plus specify minimum Fall times, which are not met with the GPIO cell; Slow strong mode can help meet this spec depending on the Bus Load.
- When the SCB is an I²C master, it interposes an IDLE state between NACK and Repeated Start; the I²C spec defines Bus free as following a Stop condition so other Active Masters do not intervene but a Master that has just become activated may start an Arbitration cycle.
- When the SCB is in I²C slave mode, and Address Match on External Clock is enabled (EC_AM = 1) along with operation in the internally clocked mode (EC_OP = 0), then its I²C address must be even.

UART Mode: This is a full-feature UART operating at up to 1 Mbps. It supports automotive single-wire interface (LIN), infrared interface (IrDA), and SmartCard (ISO7816) protocols, all of which are minor variants of the basic UART protocol. In addition, it supports the 9-bit multiprocessor mode that allows addressing of peripherals connected over common RX and TX lines. Common UART functions such as parity error, break detect, and frame error are supported. An 8-deep FIFO allows much greater CPU service latencies to be tolerated.

SPI Mode: The SPI mode supports full Motorola SPI, TI SSP (essentially adds a start pulse used to synchronize SPI Codecs), and National Microwire (half-duplex form of SPI). The SPI block can use the FIFO.



GPIO

PSoC 4100 has 36 GPIOs. The GPIO block implements the following:

- Eight drive strength modes:
 - Analog input mode (input and output buffers disabled)
 Input only
 - Weak pull-up with strong pull-down
 - □ Strong pull-up with weak pull-down
 - Open drain with strong pull-down
 - Open drain with strong pull-up
 - □ Strong pull-up with strong pull-down
 - Weak pull-up with weak pull-down
- Input threshold select (CMOS or LVTTL).
- Individual control of input and output buffer enabling/disabling in addition to the drive strength modes.
- Hold mode for latching previous state (used for retaining I/O state in Deep Sleep mode and Hibernate modes).
- Selectable slew rates for dV/dt related noise control to improve EMI.

The pins are organized in logical entities called ports, which are 8-bit in width. During power-on and reset, the blocks are forced to the disable state so as not to crowbar any inputs and/or cause excess turn-on current. A multiplexing network known as a high-speed I/O matrix is used to multiplex between various signals that may connect to an I/O pin. Pin locations for fixed-function peripherals are also fixed to reduce internal multiplexing complexity.

Data output and pin state registers store, respectively, the values to be driven on the pins and the states of the pins themselves. Every I/O pin can generate an interrupt if so enabled and each I/O port has an interrupt request (IRQ) and interrupt service routine (ISR) vector associated with it (5 for PSoC 4100 since it has 4.5 ports).

Special Function Peripherals

LCD Segment Drive

PSoC 4100 has an LCD controller which can drive up to four commons and up to 32 segments. It uses full digital methods to drive the LCD segments requiring no generation of internal LCD voltages. The two methods used are referred to as digital correlation and PWM.

Digital correlation pertains to modulating the frequency and levels of the common and segment signals to generate the highest RMS voltage across a segment to light it up or to keep the RMS signal zero. This method is good for STN displays but may result in reduced contrast with TN (cheaper) displays.

PWM pertains to driving the panel with PWM signals to effectively use the capacitance of the panel to provide the integration of the modulated pulse-width to generate the desired LCD voltage. This method results in higher power consumption but can result in better results when driving TN displays.

CapSense

CapSense is supported on all pins in the PSoC 4100 through a CapSense Sigma-Delta (CSD) block that can be connected to any pin through an analog mux bus that any GPIO pin can be connected to via an Analog switch. CapSense function can thus be provided on any pin or group of pins in a system under software control. A component is provided for the CapSense block to make it easy for the user.

Shield voltage can be driven on another mux bus to provide water tolerance capability. Water tolerance is provided by driving the shield electrode in phase with the sense electrode to keep the shield capacitance from attenuating the sensed input.

The CapSense block has two IDACs which can be used for general purposes if CapSense is not being used.(both IDACs are available in that case) or if CapSense is used without water tolerance (one IDAC is available).

WLCSP Package Bootloader

The WLCSP package is supplied with an I²C Bootloader installed in flash. The bootloader is compatible with PSoC Creator bootloadable project files and has the following default settings:

- I²C SCL and SDA connected to port pins P4.0 and P4.1 respectively (external pull-up resistors required)
- I²C Slave mode, address 8, data rate = 100 kbps
- Single application
- Wait two seconds for bootload command
- Other bootloader options are as set by the PSoC Creator Bootloader Component default
- Occupies the bottom 4.5 K of flash

For more information on this bootloader, see the following Cypress application notes:

AN73854 - Introduction to Bootloaders

Note that a PSoC Creator bootloadable project must be associated with *.hex* and *.elf* files for a bootloader project that is configured for the target device. Bootloader *.hex* and *.elf* files can be found at http://www.cypress.com/?rID=78805. The factory-installed bootloader can be overwritten using JTAG or SWD programming.



Pinouts

The following is the pin-list for PSoC 4100 (44-TQFP, 40-QFN, 28-SSOP, and 48-TQFP). Port 2 comprises of the high-speed Analog inputs for the SAR Mux. P1.7 is the optional external input and bypass for the SAR reference. Ports 3 and 4 contain the Digital Communication channels. All pins support CSD CapSense and analog mux bus connections.

44	4-TQFP	40)-QFN	28	3-SSOP	48	-TQFP		Alte	rnate Functions f	or Pins		Din Description
Pin	Name	Pin	Name	Pin	Name	Pin	Name	Analog	Alt 1	Alt 2	Alt 3	Alt 4	Pin Description
1	VSS	-	-	-	-	-	-	-	-	-	-	-	Ground
2	P2.0	1	P2.0	-	-	2	P2.0	sarmux.0	-	-	-	-	Port 2 Pin 0: gpio, lcd, csd, sarmux
3	P2.1	2	P2.1	-	-	3	P2.1	sarmux.1	-	-	-	-	Port 2 Pin 1: gpio, lcd, csd, sarmux
4	P2.2	3	P2.2	5	P2.2	4	P2.2	sarmux.2	-	-	-	-	Port 2 Pin 2: gpio, lcd, csd, sarmux
5	P2.3	4	P2.3	6	P2.3	5	P2.3	sarmux.3	-	-	-	-	Port 2 Pin 3: gpio, lcd, csd, sarmux
6	P2.4	5	P2.4	7	P2.4	6	P2.4	sarmux.4	tcpwm0_p[1]	-	-	-	Port 2 Pin 4: gpio, lcd, csd, sarmux, pwm
7	P2.5	6	P2.5	8	P2.5	7	P2.5	sarmux.5	tcpwm0_n[1]	-	-	-	Port 2 Pin 5: gpio, lcd, csd, sarmux, pwm
8	P2.6	7	P2.6	9	P2.6	8	P2.6	sarmux.6	tcpwm1_p[1]	-	-	-	Port 2 Pin 6: gpio, lcd, csd, sarmux, pwm
9	P2.7	8	P2.7	10	P2.7	9	P2.7	sarmux.7	tcpwm1_n[1]	-	-	-	Port 2 Pin 7: gpio, lcd, csd, sarmux, pwm
10	VSS	9	VSS	-	-	-	-	-	-	-	-	-	Ground
-	-	-	-	-	-	10	NC	-	-	-	-	-	No Connect
_	_	-	-	-	-	11	NC	-	-	-	-	-	No Connect
11	P3.0	10	P3.0	11	P3.0	12	P3.0	-	tcpwm0_p[0]	scb1_uart_rx[0]	scb1_i2c_scl[0]	scb1_spi_mosi[0]	Port 3 Pin 0: gpio, lcd, csd, pwm, scb1
12	P3.1	11	P3.1	12	P3.1	13	P3.1	-	tcpwm0_n[0]	scb1_uart_tx[0]	scb1_i2c_sda[0]	scb1_spi_miso[0]	Port 3 Pin 1: gpio, lcd, csd, pwm, scb1
13	P3.2	12	P3.2	13	P3.2	14	P3.2	-	tcpwm1_p[0]	_	swd_io[0]	scb1_spi_clk[0]	Port 3 Pin 2: gpio, lcd, csd, pwm, scb1, swd
-	-	-	-	-	-	15	VSSD	-	-	-	-	-	Ground
14	P3.3	13	P3.3	14	P3.3	16	P3.3	-	tcpwm1_n[0]	_	swd_clk[0]	scb1_spi_ssel_0[0]	Port 3 Pin 3: gpio, lcd, csd, pwm, scb1, swd
15	P3.4	14	P3.4	-	-	17	P3.4	-	tcpwm2_p[0]	-	-	scb1_spi_ssel_1	Port 3 Pin 4: gpio, lcd, csd, pwm, scb1
16	P3.5	15	P3.5	-	-	18	P3.5	-	tcpwm2_n[0]	-	-	scb1_spi_ssel_2	Port 3 Pin 5: gpio, lcd, csd, pwm, scb1
17	P3.6	16	P3.6	-	-	19	P3.6	-	tcpwm3_p[0]	-	-	scb1_spi_ssel_3	Port 3 Pin 6: gpio, lcd, csd, pwm, scb1
18	P3.7	17	P3.7	-	-	20	P3.7	-	tcpwm3_n[0]	-	-	-	Port 3 Pin 7: gpio, lcd, csd, pwm
19	VDDD	-	-	-	-	21	VDDD	-	-	-	-	-	Digital Supply, 1.8 - 5.5V
20	P4.0	18	P4.0	15	P4.0	22	P4.0	-	-	scb0_uart_rx	scb0_i2c_scl	scb0_spi_mosi	Port 4 Pin 0: gpio, lcd, csd, scb0
21	P4.1	19	P4.1	16	P4.1	23	P4.1	-	-	scb0_uart_tx	scb0_i2c_sda	scb0_spi_miso	Port 4 Pin 1: gpio, lcd, csd, scb0
22	P4.2	20	P4.2	17	P4.2	24	P4.2	csd_c_mod	-	-	-	scb0_spi_clk	Port 4 Pin 2: gpio, lcd, csd, scb0
23	P4.3	21	P4.3	18	P4.3	25	P4.3	csd_c_sh_tank	-	-	-	scb0_spi_ssel_0	Port 4 Pin 3: gpio, lcd, csd, scb0
-	-	-	-	-	-	26	NC	-	-	-	-	-	No Connect
-	-	-	-	-	-	27	NC	-	-	-	-	-	No Connect

PSoC[®] 4: PSoC 4100 Family Datasheet



4	4-TQFP	4	0-QFN	28-SSOP		4	8-TQFP		Alte	Pin Description			
Pin	Name	Pin	Name	Pin	Name	Pin	Name	Analog	Alt 1	Alt 2	Alt 3	Alt 4	Pin Description
24	P0.0	22	P0.0	19	P0.0	28	P0.0	comp1_inp	-	-	-	scb0_spi_ssel_1	Port 0 Pin 0: gpio, lcd, csd, scb0, comp
25	P0.1	23	P0.1	20	P0.1	29	P0.1	comp1_inn	-	-	-	scb0_spi_ssel_2	Port 0 Pin 1: gpio, lcd, csd, scb0, comp
26	P0.2	24	P0.2	21	P0.2	30	P0.2	comp2_inp	-	-	-	scb0_spi_ssel_3	Port 0 Pin 2: gpio, lcd, csd, scb0, comp
27	P0.3	25	P0.3	22	P0.3	31	P0.3	comp2_inn	-	-	-	-	Port 0 Pin 3: gpio, lcd, csd, comp
28	P0.4	26	P0.4	-	-	32	P0.4	-	-	scb1_uart_rx[1]	scb1_i2c_scl[1]	scb1_spi_mosi[1]	Port 0 Pin 4: gpio, lcd, csd, scb1
29	P0.5	27	P0.5	_	-	33	P0.5	-	-	scb1_uart_tx[1]	scb1_i2c_sda[1]	scb1_spi_miso[1]	Port 0 Pin 5: gpio, lcd, csd, scb1
30	P0.6	28	P0.6	23	P0.6	34	P0.6	-	ext_clk	-	-	scb1_spi_clk[1]	Port 0 Pin 6: gpio, lcd, csd, scb1, ext_clk
31	P0.7	29	P0.7	24	P0.7	35	P0.7	-	-	-	wakeup	scb1_spi_ssel_0[1]	Port 0 Pin 7: gpio, lcd, csd, scb1, wakeup
32	XRES	30	XRES	25	XRES	36	XRES	-	-	-	-	-	Chip reset, active low
33	VCCD	31	VCCD	26	VCCD	37	VCCD	-	-	-	-	-	Regulated supply, connect to 1µF cap or 1.8V
-	-	-	-	_	-	38	VSSD	-	-	-	-	-	Digital Ground
34	VDDD	32	VDDD	27	VDD	39	VDDD	-	-	-	-	-	Digital Supply, 1.8 - 5.5V
35	VDDA	33	VDDA	27	VDD	40	VDDA	-	-	-	-	-	Analog Supply, 1.8 - 5.5V, equal to VDDD
36	VSSA	34	VSSA	28	VSS	41	VSSA	-	-	-	-	-	Analog Ground
37	P1.0	35	P1.0	1	P1.0	42	P1.0	ctb.oa0.inp	tcpwm2_p[1]	-	-	-	Port 1 Pin 0: gpio, lcd, csd, ctb, pwm
38	P1.1	36	P1.1	2	P1.1	43	P1.1	ctb.oa0.inm	tcpwm2_n[1]	-	-	-	Port 1 Pin 1: gpio, lcd, csd, ctb, pwm
39	P1.2	37	P1.2	3	P1.2	44	P1.2	ctb.oa0.out	tcpwm3_p[1]	-	-	-	Port 1 Pin 2: gpio, lcd, csd, ctb, pwm
40	P1.3	38	P1.3	_	-	45	P1.3	ctb.oa1.out	tcpwm3_n[1]	-	-	-	Port 1 Pin 3: gpio, lcd, csd, ctb, pwm
41	P1.4	39	P1.4	-	-	46	P1.4	ctb.oa1.inm	-	-	-	-	Port 1 Pin 4: gpio, lcd, csd, ctb
42	P1.5	-	-	-	-	47	P1.5	ctb.oa1.inp	-	-	-	-	Port 1 Pin 5: gpio, lcd, csd, ctb
43	P1.6	-	-	-	-	48	P1.6	ctb.oa0.inp_alt	-	-	-	-	Port 1 Pin 6: gpio, lcd, csd
44	P1.7/VREF	40	P1.7/VREF	4	P1.7/VREF	1	P1.7/VREF	ctb.oa1.inp_alt ext_vref	-	-	-	_	Port 1 Pin 7: gpio, lcd, csd, ext_ref

Notes:

1. tcpwm_p and tcpwm_n refer to tcpwm non-inverted and inverted outputs respectively.

2. P3.2 and P3.3 are SWD pins after boot (reset).



The following is the pin-list for the PSoC 4100 (35-WLCSP).

35-E	Ball CSP		Alte	ernate Functions	for Pins		Din Description
Pin	Name	Analog	Alt 1	Alt 2	Alt 3	Alt 4	Pin Description
D3	P2.2	sarmux.2	_	-	_	-	Port 2 Pin 2: gpio, lcd, csd, sarmux
E4	P2.3	sarmux.3	_	-	_	_	Port 2 Pin 3: gpio, lcd, csd, sarmux
E5	P2.4	sarmux.4	tcpwm0_p[1]	-	-	-	Port 2 Pin 4: gpio, lcd, csd, sarmux, pwm
E6	P2.5	sarmux.5	tcpwm0_n[1]	-	-	-	Port 2 Pin 5: gpio, lcd, csd, sarmux, pwm
E3	P2.6	sarmux.6	tcpwm1_p[1]	-	-	-	Port 2 Pin 6: gpio, lcd, csd, sarmux, pwm
E2	P2.7	sarmux.7	tcpwm1_n[1]	-	-	-	Port 2 Pin 7: gpio, lcd, csd, sarmux, pwm
E1	P3.0	-	tcpwm0_p[0]	scb1_uart_rx[0]	scb1_i2c_scl[0]	scb1_spi_mosi[0]	Port 3 Pin 0: gpio, lcd, csd, pwm, scb1
D2	P3.1	-	tcpwm0_n[0]	scb1_uart_tx[0]	scb1_i2c_sda[0]	scb1_spi_miso[0]	Port 3 Pin 1: gpio, lcd, csd, pwm, scb1
D1	P3.2	-	tcpwm1_p[0]	-	swd_io[0]	scb1_spi_clk[0]	Port 3 Pin 2: gpio, lcd, csd, pwm, scb1, swd
B7	VSS	-	-	-	-	-	Ground
C1	P3.3	-	tcpwm1_n[0]	-	swd_clk[0]	scb1_spi_ssel_0[0]	Port 3 Pin 3: gpio, lcd, csd, pwm, scb1, swd
C2	P3.4	-	tcpwm2_p[0]	-	-	scb1_spi_ssel_1	Port 3 Pin 4: gpio, lcd, csd, pwm, scb1
B1	P4.0	-	_	scb0_uart_rx	scb0_i2c_scl	scb0_spi_mosi	Port 4 Pin 0: gpio, lcd, csd, scb0
B2	P4.1	-	-	scb0_uart_tx	scb0_i2c_sda	scb0_spi_miso	Port 4 Pin 1: gpio, lcd, csd, scb0
A2	P4.2	csd_c_mod	_	-	-	scb0_spi_clk	Port 4 Pin 2: gpio, lcd, csd, scb0
A1	P4.3	csd_c_sh_tank	-	-	-	scb0_spi_ssel_0	Port 4 Pin 3: gpio, lcd, csd, scb0
C3	P0.0	comp1_inp	_	-	-	scb0_spi_ssel_1	Port 0 Pin 0: gpio, lcd, csd, scb0, comp
A5	P0.1	comp1_inn	-	-	-	scb0_spi_ssel_2	Port 0 Pin 1: gpio, lcd, csd, scb0, comp
A4	P0.2	comp2_inp	_	-	-	scb0_spi_ssel_3	Port 0 Pin 2: gpio, lcd, csd, scb0, comp
A3	P0.3	comp2_inn	_	_	_	-	Port 0 Pin 3: gpio, lcd, csd, comp
B3	P0.4	-	_	scb1_uart_rx[1]	scb1_i2c_scl[1]	scb1_spi_mosi[1]	Port 0 Pin 4: gpio, lcd, csd, scb1
A6	P0.5	-	_	scb1_uart_tx[1]	scb1_i2c_sda[1]	scb1_spi_miso[1]	Port 0 Pin 5: gpio, lcd, csd, scb1
B4	P0.6	-	ext_clk	_	_	scb1_spi_clk[1]	Port 0 Pin 6: gpio, lcd, csd, scb1, ext_clk
B5	P0.7	_	_	-	wakeup	scb1_spi_ssel_0[1]	Port 0 Pin 7: gpio, lcd, csd, scb1, wakeup
B6	XRES	_	_	-	_	-	Chip reset, active low
A7	VCCD	-	-	-	-	-	Regulated supply, connect to 1µF cap or 1.8V
C7	VDD	_	_	-	_	-	Supply, 1.8 - 5.5V
C4	P1.0	ctb.oa0.inp	tcpwm2_p[1]	-	_	-	Port 1 Pin 0: gpio, lcd, csd, ctb, pwm
C5	P1.1	ctb.oa0.inm	tcpwm2_n[1]	-	_	-	Port 1 Pin 1: gpio, lcd, csd, ctb, pwm



35-	Ball CSP		Alte	rnate Functions	for Pins		Pin Description
Pin	Name	Analog	Alt 1	Alt 2	Alt 3	Alt 4	
C6	P1.2	ctb.oa0.out	tcpwm3_p[1]	_	_	-	Port 1 Pin 2: gpio, lcd, csd, ctb, pwm
D7	P1.3	ctb.oa1.out	tcpwm3_n[1]	-	-	-	Port 1 Pin 3: gpio, lcd, csd, ctb, pwm
D4	P1.4	ctb.oa1.inm	-	-	-	-	Port 1 Pin 4: gpio, lcd, csd, ctb
D5	P1.5	ctb.oa1.inp	_	-	-	-	Port 1 Pin 5: gpio, lcd, csd, ctb
D6	P1.6	ctb.oa0.inp_alt	-	-	-	-	Port 1 Pin 6: gpio, lcd, csd
E7	P1.7/VREF	ctb.oa1.inp_alt ext_vref	_	_	-	_	Port 1 Pin 7: gpio, lcd, csd, ext_ref

Descriptions of the Pin functions are as follows:

VDDD: Power supply for both analog and digital sections (where there is no V_{DDA} pin).

VDDA: Analog V_{DD} pin where package pins allow; shorted to V_{DDD} otherwise.

VSSA: Analog ground pin where package pins allow; shorted to VSS otherwise

VSS: Ground pin.

VCCD: Regulated Digital supply (1.8 V ±5%).

Port Pins can all be used as LCD Commons, LCD Segment drivers, or CSD sense and shield pins can be connected to AMUXBUS A or B or can all be used as GPIO pins that can be driven by firmware or DSI signals.

The following packages are supported: 48-pin TQFP, 44-pin TQFP, 40-pin QFN, and 28-pin SSOP.



Figure 5. 48-Pin TQFP Pinout

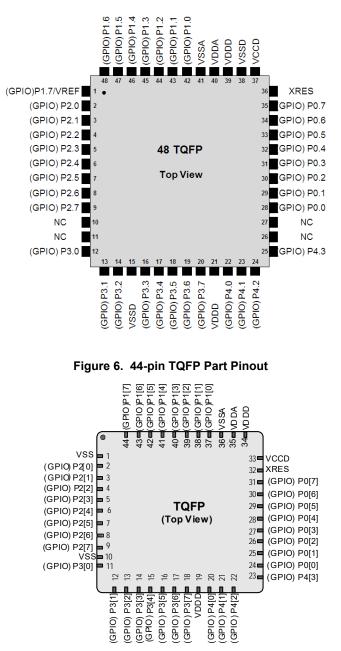




Figure 7. 40-Pin QFN Pinout

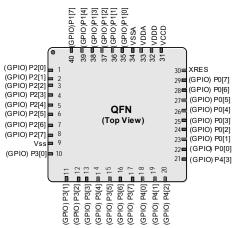


Figure 8. 35-Ball WLCSP

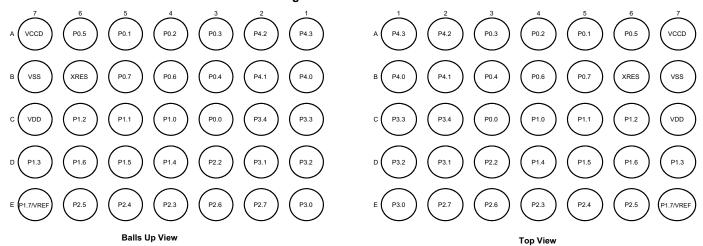


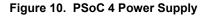
Figure 9. 28-Pin SSOP Pinout

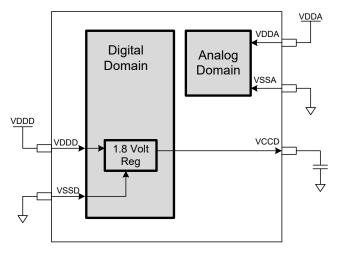
ſ	0			
(GPIO) P1[0]	• 1		28 🖛	VSS
(GPIO)P1[1]	2		27 🗖	VDDD
(GPIO)P1[2]	3		26 🗖	VCCD
(GPIO) P1[7]	4		25 🖛	XRES
(GPIO) P2[2]	5		24 📼	(GPIO)P0[7]
(GPIO) P2[3]	6	SSOP	23 🗖	(GPIO) P0[6]
(GPIO) P2[4]	7	(Top View)	22 🗖	(GPIO) P0[3]
(GPIO) P2[5]	8		21 🗖	(GPIO) P0[2]
(GPIO) P2[6]	9		20 🖛	(GPIO) P0[1]
(GPIO)P2[7]	1 0		19 🗖	(GPIO) P0[0]
	1 1		18 🖛	(GPIO) P4[3]
(GPIO)P3[1]	12		17 🖛	(GPIO)P4[2]
(GPIO)P3[2]	1 3		16 🗖	(GPIO)P4[1]
(GPIO)P3[3]	1 4		15 🖛	(GPIO) P4[0]
			J	



Power

The following power system diagrams show the minimum set of power supply pins as implemented for PSoC 4100. The system has one regulator in Active mode for the digital circuitry. There is no analog regulator; the analog circuits run directly from the V_{DDA} input. There are separate regulators for the Deep Sleep and Hibernate (lowered power supply and retention) modes. There is a separate low-noise regulator for the bandgap. The supply voltage range is 1.71 V to 5.5 V with all functions and circuits operating over that range.





The PSoC 4100 family allows two distinct modes of power supply operation: Unregulated External Supply, and Regulated External Supply modes.

Unregulated External Supply

In this mode, PSoC 4100 is powered by an external power supply that can be anywhere in the range of 1.8 V to 5.5 V. This range is also designed for battery-powered operation, for instance, the chip can be powered from a battery system that starts at 3.5 V and works down to 1.8 V. In this mode, the internal regulator of PSoC 4100 supplies the internal logic and the V_{CCD} output of the PSoC 4100 must be bypassed to ground via an external Capacitor (in the range of 1 μ F to 1.6 μ F; X5R ceramic or better).

 V_{DDA} and V_{DDD} must be shorted together; the grounds, VSSA and V_{SS} must also be shorted together. Bypass capacitors must be used from V_{DDD} to ground, typical practice for systems in this frequency range is to use a capacitor in the 1- μF range in parallel with a smaller capacitor (0.1 μF for example). Note that these are simply rules of thumb and that, for critical applications, the PCB layout, lead inductance, and the Bypass capacitor parasitic should be simulated to design and obtain optimal bypassing.

Figure 11. 48-TQFP Package Example

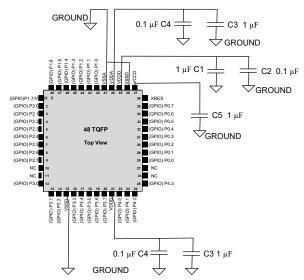
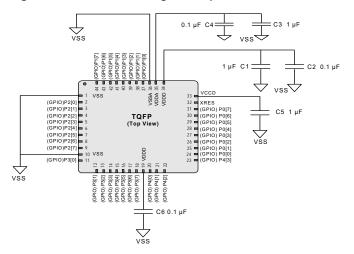


Figure 12. 44-TQFP Package Example



Power Supply	Bypass Capacitors
VDDD-VSS	0.1 μ F ceramic at each pin (C2, C6) plus bulk capacitor 1 to 10 μ F (C1). Total capac- itance may be greater than 10 μ F.
VDDA-VSSA	0.1 μ F ceramic at pin (C4). Additional 1 μ F to 10 μ F (C3) bulk capacitor. Total capacitance may be greater than 10 μ F.
VCCD-VSS	1 μF ceramic capacitor at the VCCD pin (C5)
VREF–VSSA (optional)	The internal bandgap may be bypassed with a 1 μ F to 10 μ F capacitor. Total capacitance may be greater than 10 μ F.



Note It is good practice to check the datasheets for your bypass capacitors, specifically the working voltage and the DC bias specifications. With some capacitors, the actual capacitance can decrease considerably when the DC bias (V_{DDA} , V_{DDD} , or V_{CCD}) is a significant percentage of the rated working voltage. V_{DDA} must be equal to or higher than the V_{DDD} supply when powering up.

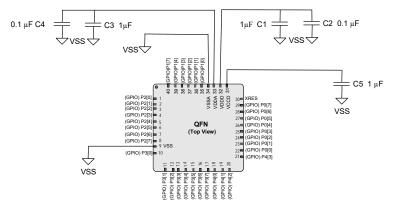
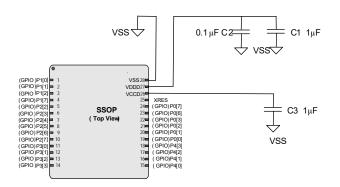


Figure 13. 40-pin QFN Example





Regulated External Supply

In this mode, the PSoC 4100 is powered by an external power supply that must be within the range of 1.71 V to 1.89 V (1.8 \pm 5%); note that this range needs to include power supply ripple too. In this mode, VCCD, VDDA, and VDDD pins are all shorted together and bypassed. The internal regulator is disabled in firmware.



Development Support

The PSoC 4100 family has a rich set of documentation, development tools, and online resources to assist you during your development process. Visit www.cypress.com/go/psoc4 to find out more.

Documentation

A suite of documentation supports the PSoC 4100 family to ensure that you can find answers to your questions quickly. This section contains a list of some of the key documents.

Software User Guide: A step-by-step guide for using PSoC Creator. The software user guide shows you how the PSoC Creator build process works in detail, how to use source control with PSoC Creator, and much more.

Component Datasheets: The flexibility of PSoC allows the creation of new peripherals (components) long after the device has gone into production. Component data sheets provide all of the information needed to select and use a particular component, including a functional description, API documentation, example code, and AC/DC specifications.

Application Notes: PSoC application notes discuss a particular application of PSoC in depth; examples include brushless DC motor control and on-chip filtering. Application notes often include example projects in addition to the application note document.

Technical Reference Manual: The Technical Reference Manual (TRM) contains all the technical detail you need to use a PSoC device, including a complete description of all PSoC registers. The TRM is available in the Documentation section at www.cypress.com/psoc4.

Online

In addition to print documentation, the Cypress PSoC forums connect you with fellow PSoC users and experts in PSoC from around the world, 24 hours a day, 7 days a week.

Tools

With industry standard cores, programming, and debugging interfaces, the PSoC 4100 family is part of a development tool ecosystem. Visit us at www.cypress.com/go/psoccreator for the latest information on the revolutionary, easy to use PSoC Creator IDE, supported third party compilers, programmers, debuggers, and development kits.



Electrical Specifications

Absolute Maximum Ratings

Table 1. Absolute Maximum Ratings^[1]

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID1	V _{DDD_ABS}	Digital supply relative to V _{SSD}	-0.5	-	6	V	Absolute max
SID2	V _{CCD_ABS}	Direct digital core voltage input relative to Vssd	-0.5	_	1.95	V	Absolute max
SID3	V _{GPIO_ABS}	GPIO voltage	-0.5	-	V _{DD} +0.5	V	Absolute max
SID4	I _{GPIO_ABS}	Maximum current per GPIO	-25	-	25	mA	Absolute max
SID5	I _{GPIO_injection}	GPIO injection current, Max for V _{IH} > V _{DDD} , and Min for V _{IL} < V _{SS}	-0.5	_	0.5	mA	Absolute max, current injected per pin
BID44	ESD_HBM	Electrostatic discharge human body model	2200	_	_	V	
BID45	ESD_CDM	Electrostatic discharge charged device model	500	-	-	V	
BID46	LU	Pin current for latch-up	-200	_	200	mA	

Device-Level Specifications

All specifications are valid for -40 °C \leq TA \leq 105 °C and TJ \leq 125 °C, except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID53	V _{DD}	Power Supply Input Voltage (V _{DDA} = V _{DDD} = V _{DD})	1.8	-	5.5	V	With regulator enabled
SID255	V _{DDD}	Power Supply Input Voltage unregu- lated	1.71	1.8	1.89	V	Internally unregulated Supply
SID54	V _{CCD}	Output voltage (for core logic)	_	1.8	-	V	
SID55	CEFC	External Regulator voltage (V _{CCD}) bypass	1	1.3	1.6	μF	X5R ceramic or better
SID56	CEXC	Power supply decoupling capacitor	_	1	_	μF	X5R ceramic or better
Active Mo	de, V _{DD} = 1.71	V to 5.5 V. Typical Values measured a	t V _{DD} = 3.	.3 V			
SID9	IDD4	Execute from Flash; CPU at 6 MHz	_	_	2.8	mA	
SID10	IDD5	Execute from Flash; CPU at 6 MHz	_	2.2	_	mA	T = 25 °C
SID12	IDD7	Execute from Flash; CPU at 12 MHz,	_	_	4.2	mA	
SID13	IDD8	Execute from Flash; CPU at 12 MHz	_	3.7	_	mA	T = 25 °C
SID16	IDD11	Execute from Flash; CPU at 24 MHz	-	6.7	-	mA	T = 25 °C
SID17	IDD12	Execute from Flash; CPU at 24 MHz	_	_	7.2	mA	
Sleep Mod	le, V _{DD} = 1.7 V	to 5.5 V					
SID25	IDD20	I ² C wakeup, WDT, and Comparators on. 6 MHz.	-	1.3	1.8	mA	V _{DD} = 1.71 to 5.5 V
SID25A	IDD20A	I ² C wakeup, WDT, and Comparators on. 12 MHz.	_	1.7	2.2	mA	V _{DD} = 1.71 to 5.5 V
Deep Slee	p Mode, V _{DD} =	1.8 V to 3.6 V (Regulator on)		•		•	-
SID31	IDD26	I ² C wakeup and WDT on.	_	1.3	_	μA	T = 25 °C

Note

Usage above the absolute maximum conditions listed in Table 1 may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods of time may affect device reliability. The maximum storage temperature is 150 °C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When used below absolute maximum conditions but above normal operating conditions, the device may not operate to specification.



Table 2. DC Specifications (continued)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID32	IDD27	I ² C wakeup and WDT on.	_	_	45	μA	T = 85 °C
Deep Slee	p Mode, V _{DD} =	3.6 V to 5.5 V					
SID34	IDD29	I ² C wakeup and WDT on	-	1.5	15	μA	Typ at 25 °C Max at 85 °C
Deep Slee	p Mode, V _{DD} =	1.71 V to 1.89 V (Regulator bypassed)			1	4
SID37	IDD32	I ² C wakeup and WDT on.	_	1.7	_	μA	T = 25 °C
SID38	IDD33	I ² C wakeup and WDT on	_	_	60	μA	T = 85 °C
Deep Slee	p Mode, +105	ŶC		•			
SID33Q	IDD28Q	I ² C wakeup and WDT on. Regulator Off.	-	-	135	μA	V _{DD} = 1.71 to 1.89
SID34Q	IDD29Q	I ² C wakeup and WDT on.	-	-	180	μA	V _{DD} = 1.8 to 3.6
SID35Q	IDD30Q	I ² C wakeup and WDT on.	_	_	140	μA	V _{DD} = 3.6 to 5.5
Hibernate	Mode, V _{DD} = 1	.8 V to 3.6 V (Regulator on)					•
SID40	IDD35	GPIO and Reset active	_	150	_	nA	T = 25 °C
SID41	IDD36	GPIO and Reset active	_	-	1000	nA	T = 85 °C
Hibernate	Mode, V _{DD} = 3	.6 V to 5.5 V					
SID43	IDD38	GPIO and Reset active	_	150	-	nA	T = 25 °C
Hibernate	Mode, V _{DD} = 1	.71 V to 1.89 V (Regulator bypassed)					
SID46	IDD41	GPIO and Reset active	_	150	-	nA	T = 25 °C
SID47	IDD42	GPIO and Reset active	_	_	1000	nA	T = 85 °C
Hibernate	Mode, +105 °C	,					
SID42Q	IDD37Q	Regulator Off	_	-	19.4	μA	V _{DD} = 1.71 to 1.89
SID43Q	IDD38Q		-	-	17	μA	V _{DD} = 1.8 to 3.6
SID44Q	IDD39Q		-	-	16	μA	V _{DD} = 3.6 to 5.5
Stop Mode	9						
SID304	IDD43A	Stop Mode current; V _{DD} = 3.3 V	-	20	80	nA	Typ at 25 °C Max at 85 °C
Stop Mode	ə, +105 °C	•		•		·	•
SID304Q	IDD43AQ	Stop Mode current; V _{DD} = 3.6 V	_	-	5645	nA	
XRES curi	rent						
SID307	IDD_XR	Supply current while XRES asserted	-	2	5	mA	

Table 3. AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID48	F _{CPU}	CPU frequency	DC	-	24	MHz	$1.71 \leq V_{DD} \leq 5.5$
SID49	T _{SLEEP}	Wakeup from sleep mode	-	0	_	μs	Guaranteed by charac- terization
SID50	T _{DEEPSLEEP}	Wakeup from Deep Sleep mode	_	_	25	μs	24-MHz IMO. Guaranteed by charac- terization
SID51	T _{HIBERNATE}	Wakeup from Hibernate and Stop modes	_	_	2	ms	Guaranteed by charac- terization
SID52	T _{RESETWIDTH}	External reset pulse width	1	_	_	μs	Guaranteed by charac- terization



GPIO

Table 4. GPIO DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID57	V _{IH} ^[2]	Input voltage high threshold	0.7 × V _{DDD}	_	_	V	CMOS Input
SID58	V _{IL}	Input voltage low threshold	-	-	0.3 × V _{DDD}	V	CMOS Input
SID241	V _{IH} ^[2]	LVTTL input, V _{DDD} < 2.7 V	0.7× V _{DDD}	-	-	V	
SID242	V _{IL}	LVTTL input, V _{DDD} < 2.7 V	-	-	0.3 × V _{DDD}	V	
SID243	V _{IH} ^[2]	LVTTL input, $V_{DDD} \ge 2.7 V$	2.0	-	-	V	
SID244	V _{IL}	LVTTL input, $V_{DDD} \ge 2.7 V$	-	-	0.8	V	
SID59	V _{OH}	Output voltage high level	V _{DDD} -0.6	-	-	V	I _{OH} = 4 mA at 3-V V _{DDD}
SID60	V _{OH}	Output voltage high level	V _{DDD} -0.5	-	-	V	I _{OH} = 1 mA at 1.8-V V _{DDD}
SID61	V _{OL}	Output voltage low level	-	-	0.4	V	I _{OL} = 4 mA at 1.8-V V _{DDD}
SID62	V _{OL}	Output voltage low level	-	-	0.6	V	I _{OL} =8 mA at 3-V V _{DDD}
SID62A	V _{OL}	Output voltage low level	-	-	0.4	V	I _{OL} =3 mA at 3-V V _{DDD}
SID63	R _{PULLUP}	Pull-up resistor	3.5	5.6	8.5	kΩ	
SID64	R _{PULLDOWN}	Pull-down resistor	3.5	5.6	8.5	kΩ	
SID65	IIL	Input leakage current (absolute value)	-	-	2	nA	25 °C, V _{DDD} = 3.0-V
SID65A	I _{IL_CTBM}	Input leakage current (absolute value) for CTBM pins	-	-	4	nA	
SID66	C _{IN}	Input capacitance	-	-	7	pF	
SID67	V _{HYSTTL}	Input hysteresis LVTTL	25	40	_	mV	$V_{DDD} \ge 2.7 V.$ Guaranteed by characterization
SID68	V _{HYSCMOS}	Input hysteresis CMOS	0.05 × V _{DDD}	-	-	mV	Guaranteed by characterization
SID69	I _{DIODE}	Current through protection diode to V_{DD}/Vss	-	-	100	μA	Guaranteed by characterization
SID69A	I _{TOT_GPIO}	Maximum Total Source or Sink Chip Current	-	-	200	mA	Guaranteed by characterization



Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID70	T _{RISEF}	Rise time in fast strong mode	2	-	12	ns	3.3-V V _{DDD} , Cload = 25 pF
SID71	T _{FALLF}	Fall time in fast strong mode	2	-	12	ns	3.3-V V _{DDD} , Cload = 25 pF
SID72	T _{RISES}	Rise time in slow strong mode	10	-	60	ns	3.3-V V _{DDD} , Cload = 25 pF
SID73	T _{FALLS}	Fall time in slow strong mode	10	_	60	ns	3.3-V V _{DDD} , Cload = 25 pF
SID74	F _{GPIOUT1}	GPIO Fout;3.3 V \leq V _{DDD} \leq 5.5 V. Fast strong mode.	-	-	24	MHz	90/10%, 25-pF load, 60/40 duty cycle
SID75	F _{GPIOUT2}	GPIO Fout;1.7 V≤ V _{DDD} ≤ 3.3 V. Fast strong mode.	_	-	16.7	MHz	90/10%, 25-pF load, 60/40 duty cycle
SID76	F _{GPIOUT3}	GPIO Fout;3.3 V \leq V _{DDD} \leq 5.5 V. Slow strong mode.	-	-	7	MHz	90/10%, 25-pF load, 60/40 duty cycle
SID245	F _{GPIOUT4}	GPIO Fout;1.7 V \leq V _{DDD} \leq 3.3 V. Slow strong mode.	-	-	3.5	MHz	90/10%, 25-pF load, 60/40 duty cycle
SID246	F _{GPIOIN}	GPIO input operating frequency; 1.71 V \leq V _{DDD} \leq 5.5 V	_	_	24	MHz	90/10% V _{IO}

Table 5. GPIO AC Specifications (Guaranteed by Characterization)

XRES

Table 6. XRES DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID77	V _{IH}	Input voltage high threshold	0.7 × V _{DDD}	-	-	V	CMOS Input
SID78	V _{IL}	Input voltage low threshold	-	-	0.3 × V _{DDD}	V	CMOS Input
SID79	R _{PULLUP}	Pull-up resistor	3.5	5.6	8.5	kΩ	
SID80	C _{IN}	Input capacitance	-	3	-	pF	
SID81	V _{HYSXRES}	Input voltage hysteresis	-	100	-	mV	Guaranteed by characterization
SID82	I _{DIODE}	Current through protection diode to $V_{DDD} N_{SS}$	_	_	100	μA	Guaranteed by characterization

Table 7. XRES AC Specifications

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID83	T _{RESETWIDTH}	Reset pulse width	1	-	_	μs	Guaranteed by characterization



Analog Peripherals

Opamp

Table 8. Opamp Specifications (Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
	I _{DD}	Opamp block current. No load.	-	-	-	-	
SID269	I _{DD_HI}	Power = high	-	1100	1850	μA	
SID270	I _{DD_MED}	Power = medium	-	550	950	μA	
SID271	I _{DD LOW}	Power = low	-	150	350	μA	
	GBW	Load = 20 pF, 0.1 mA. V _{DDA} = 2.7 V	-	-	_	-	
SID272	GBW_HI	Power = high	6	-	-	MHz	
SID273	GBW_MED	Power = medium	4	-	-	MHz	
SID274	GBW_LO	Power = low	_	1	-	MHz	
	I _{OUT_MAX}	V _{DDA} ≥ 2.7 V, 500 mV from rail	_	-	-	-	
SID275	I _{OUT_MAX_HI}	Power = high	10	-	-	mA	
SID276	I _{OUT_MAX_MID}	Power = medium	10	-	-	mA	
SID277	I _{OUT_MAX_LO}	Power = low	_	5	_	mA	
	I _{OUT}	V _{DDA} = 1.71 V, 500 mV from rail	_	_	_	_	
SID278	I _{OUT_MAX_HI}	Power = high	4	-	-	mA	
SID279	I _{OUT_MAX_MID}	Power = medium	4	_	_	mA	
SID280	I _{OUT_MAX_LO}	Power = low	_	2	_	mA	
SID281	V _{IN}	Charge pump on, $V_{DDA} \ge 2.7 V$	-0.05	_	V _{DDA} - 0.2	V	
SID282	V _{CM}	Charge pump on, $V_{DDA} \ge 2.7 \text{ V}$	-0.05	_	$V_{DDA} - 0.2$	V	
	V _{OUT}	$V_{DDA} \ge 2.7 V$	_	_	-		
SID283	V _{OUT_1}	Power = high, lload=10 mA	0.5	_	V _{DDA} – 0.5	V	
SID284	V _{OUT_2}	Power = high, lload=1 mA	0.2	_	$V_{DDA} - 0.2$	V	
SID285	V _{OUT_3}	Power = medium, lload=1 mA	0.2	_	$V_{DDA} - 0.2$	V	
SID286	V _{OUT_4}	Power = low, lload=0.1 mA	0.2	_	$V_{DDA} - 0.2$	V	
SID288	V _{OS_TR}	Offset voltage, trimmed	1	±0.5	1	mV	High mode
SID288A	V _{OS_TR}	Offset voltage, trimmed	_	±1	_	mV	Medium mode
SID288B	V _{OS_TR}	Offset voltage, trimmed	_	±2	_	mV	Low mode
SID290	V _{OS_DR_TR}	Offset voltage drift, trimmed	-10	±3	10	µV/°C	High mode. T _A ≤ 85 °C
SID290Q	VOS_DR_TR	Offset voltage drift, trimmed	15	±3	15	µV/°C	High mode. T _A ≤ 105 °C
SID290A	V _{OS_DR_TR}	Offset voltage drift, trimmed	_	±10	_	µV/°C	Medium mode
SID290B	V _{OS_DR_TR}	Offset voltage drift, trimmed	_	±10	_	μV/°C	Low mode
SID291	CMRR	DC	70	80	_	dB	V _{DDD} = 3.6 V
SID292	PSRR	At 1 kHz, 100-mV ripple	70	85	_	dB	V _{DDD} = 3.6 V
	Noise		_	_	_	_	
SID293	V _{N1}	Input referred, 1 Hz - 1GHz, power = high	-	94	-	μVrms	
SID294	V _{N2}	Input referred, 1 kHz, power = high	_	72	_	nV/rtHz	
SID295	V _{N3}	Input referred, 10kHz, power = high	-	28	_	nV/rtHz	
SID296	V _{N4}	Input referred, 100kHz, power = high	_	15	_	nV/rtHz	



Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID297	Cload	Stable up to maximum load. Perfor- mance specs at 50 pF.	-	Ι	125	pF	
SID298	Slew_rate	Cload = 50 pF, Power = High, $V_{DDA} \ge 2.7 V$	6	_	_	V/µs	
SID299	T_op_wake	From disable to enable, no external RC dominating	-	300	_	μs	
SID299A	OL_GAIN	Open Loop Gain	-	90	-	dB	Guaranteed by design
	Comp_mode	Comparator mode; 50-mV drive, Trise = Tfall (approx)	-	-	-		
SID300	T _{PD1}	Response time; power = high	_	150	_	ns	
SID301	T _{PD2}	Response time; power = medium	_	400	-	ns	
SID302	T _{PD3}	Response time; power = low	_	2000	_	ns	
SID303	Vhyst_op	Hysteresis	—	10	—	mV	

Table 8. Opamp Specifications (Guaranteed by Characterization) (continued)

Comparator

Table 9. Comparator DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID85	V _{OFFSET2}	Input offset voltage, Common Mode voltage range from 0 to V _{DD} -1	-	-	±4	mV	
SID85A	V _{OFFSET3}	Input offset voltage. Ultra low-power mode ($V_{DDD} \ge 2.2 \text{ V}$ for Temp < 0 °C, $V_{DDD} \ge 1.8 \text{ V}$ for Temp > 0 °C)	-	±12	-	mV	
SID86	V _{HYST}	Hysteresis when enabled, Common Mode voltage range from 0 to V_{DD} -1.	_	10	35	mV	Guaranteed by characterization
SID87	V _{ICM1}	Input common mode voltage in normal mode	0	-	V _{DDD} – 0.1	V	Modes 1 and 2.
SID247	V _{ICM2}	Input common mode voltage in low power mode ($V_{DDD} \ge 2.2 \text{ V}$ for Temp < 0 °C, $V_{DDD} \ge 1.8 \text{ V}$ for Temp > 0 °C)	0	-	V _{DDD}	V	
SID247A	V _{ICM3}	Input common mode voltage in ultra low power mode	0	-	V _{DDD} – 1.15	V	
SID88	CMRR	Common mode rejection ratio	50	-	-	dB	$V_{DDD} \ge 2.7 V.$ Guaranteed by characterization
SID88A	CMRR	Common mode rejection ratio	42	-	-	dB	V _{DDD} < 2.7 V. Guaranteed by characterization
SID89	I _{CMP1}	Block current, normal mode	-	-	400	μA	Guaranteed by characterization
SID248	I _{CMP2}	Block current, low power mode	-	-	100	μA	Guaranteed by characterization
SID259	I _{CMP3}	Block current, ultra low power mode ($V_{DDD} \ge 2.2 \text{ V}$ for Temp < 0 °C, $V_{DDD} \ge 1.8 \text{ V}$ for Temp > 0 °C)	_	6	28	μA	Guaranteed by characterization
SID90	Z _{CMP}	DC input impedance of comparator	35	_	-	MΩ	Guaranteed by characterization



Table 10. Comparator AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID91	T _{RESP1}	Response time, normal mode	-	-	110	ns	50-mV overdrive
SID258	T _{RESP2}	Response time, low power mode	_	-	200	ns	50-mV overdrive
SID92	T _{RESP3}	Response time, ultra low power mode (V _{DDD} ≥ 2.2 V for Temp < 0 °C, V _{DDD} ≥ 1.8 V for Temp > 0 °C)	_	_	15	μs	200-mV overdrive

Temperature Sensor

Table 11. Temperature Sensor Specifications

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID93	T _{SENSACC}	Temperature sensor accuracy	-5	±1	+5	°C	–40 to +85 °C

SAR ADC

Table 12. SAR ADC DC Specifications

Spec ID#	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID94	A_RES	Resolution	-	-	12	bits	
SID95	A_CHNIS_S	Number of channels - single ended	-	-	8		
SID96	A-CHNKS_D	Number of channels - differential	-	-	4		Diff inputs use neighboring I/O
SID97	A-MONO	Monotonicity	-	-	-		Yes. Based on characterization
SID98	A_GAINERR	Gain error	-	_	±0.1	%	With external reference. Guaranteed by characterization
SID99	A_OFFSET	Input offset voltage	-	-	2	mV	Measured with 1-V V _{REF.} Guaranteed by characterization
SID100	A_ISAR	Current consumption	-	-	1	mA	
SID101	A_VINS	Input voltage range - single ended	V _{SS}	-	V _{DDA}	V	Based on device characterization
SID102	A_VIND	Input voltage range - differential	V _{SS}	-	V _{DDA}	V	Based on device characterization
SID103	A_INRES	Input resistance	-	-	2.2	KΩ	Based on device characterization
SID104	A_INCAP	Input capacitance	-	-	10	pF	Based on device characterization
SID106	A_PSRR	Power supply rejection ratio	70	-	-	dB	
SID107	A_CMRR	Common mode rejection ratio	66	-	-	dB	Measured at 1 V
SID111	A_INL	Integral non linearity	-1.7	-	+2	LSB	V _{DD} = 1.71 to 5.5, 806 ksps, V _{REF} = 1 to 5.5.
SID111A	A_INL	Integral non linearity	-1.5	-	+1.7	LSB	V _{DDD} = 1.71 to 3.6, 806 ksps, V _{REF} = 1.71 to V _{DDD} .



Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID111B	A_INL	Integral non linearity	-1.5	-	+1.7	LSB	V _{DDD} = 1.71 to 5.5, 500 ksps, V _{REF} = 1 to 5.5.
SID112	A_DNL	Differential non linearity	-1	_	+2.2	LSB	V _{DDD} = 1.71 to 5.5, 806 ksps, V _{REF} = 1 to 5.5.
SID112A	A_DNL	Differential non linearity	-1	_	+2	LSB	V _{DDD} = 1.71 to 3.6, 806 ksps, V _{REF} = 1.71 to V _{DDD} .
SID112B	A_DNL	Differential non linearity	-1	_	+2.2	LSB	V _{DDD} = 1.71 to 5.5, 500 ksps, V _{REF} = 1 to 5.5.

Table 12. SAR ADC DC Specifications (continued)

Table 13. SAR ADC AC Specifications (Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID108	A_SAMP_1	Sample rate with external reference bypass cap	_	-	806	ksps	
SID108A	A_SAMP_2	Sample rate with no bypass cap. Reference = V _{DD}	-	-	500	ksps	
SID108B	A_SAMP_3	Sample rate with no bypass cap. Internal reference	_	-	100	ksps	
SID109	A_SNDR	Signal-to-noise and distortion ratio (SINAD)	65	-	_	dB	F _{IN} = 10 kHz
SID113	A_THD	Total harmonic distortion	_	-	-65	dB	F _{IN} = 10 kHz.



CSD

Table 14. CSD Specifications

Spec ID#	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID.CSD#16	IDAC1IDD	IDAC1 (8 bits) block current	_	_	1125	μA	
SID.CSD#17	IDAC2IDD	IDAC2 (7 bits) block current	-	_	1125	μA	
SID308	VCSD	Voltage range of operation	1.71	-	5.5	V	
SID308A	VCOMPIDAC	Voltage compliance range of IDAC for S0	0.8	-	V _{DD} -0.8	V	
SID309	IDAC1	DNL for 8-bit resolution	-1	-	1	LSB	
SID310	IDAC1	INL for 8-bit resolution	-3	_	3	LSB	
SID311	IDAC2	DNL for 7-bit resolution	-1	_	1	LSB	
SID312	IDAC2	INL for 7-bit resolution	-3	-	3	LSB	
SID313	SNR	Ratio of counts of finger to noise, 0.1-pF sensitivity	5	_	_	Ratio	Capacitance range of 9 to 35 pF, 0.1-pF sensitivity
SID314	IDAC1_CRT1	Output current of IDAC1 (8 bits) in High range	_	612	-	uA	
SID314A	IDAC1_CRT2	Output current of IDAC1 (8 bits) in Low range	-	306	-	uA	
SID315	IDAC2_CRT1	Output current of IDAC2 (7 bits) in High range	-	304.8	-	uA	
SID315A	IDAC2_CRT2	Output current of IDAC2 (7 bits) in Low range	-	152.4	-	uA	
SID320	IDACOFFSET	All zeroes input	_	-	±1	LSB	
SID321	IDACGAIN	Full-scale error less offset	_	-	±10	%	
SID322	IDACMISMATCH	Mismatch between IDACs	_	-	7	LSB	
SID323	IDACSET8	Settling time to 0.5 LSB for 8-bit IDAC	_	-	10	μs	Full-scale transition. No external load.
SID324	IDACSET7	Settling time to 0.5 LSB for 7-bit IDAC	_	-	10	μs	Full-scale transition. No external load.
SID325	CMOD	External modulator capacitor	-	2.2	-	nF	5-V rating, X7R or NP0 cap.



Digital Peripherals

The following specifications apply to the Timer/Counter/PWM peripheral in timer mode.

Timer/Counter/PWM

Table 15. TCPWM Specifications

(Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID.TCPWM.1	ITCPWM1	Block current consumption at 3 MHz	-	-	45	μA	All modes (TCPWM)
SID.TCPWM.2	ITCPWM2	Block current consumption at 12 MHz	-	-	155	μA	All modes (TCPWM)
SID.TCPWM.2A	ITCPWM3	Block current consumption at 48 MHz	-	-	650	μA	All modes (TCPWM)
SID.TCPWM.3	TCPWMFREQ	Operating frequency	-	-	Fc	MHz	Fc max = Fcpu. Maximum = 24 MHz
SID.TCPWM.4	TPWMENEXT	Input Trigger Pulse Width for all Trigger Events	2/Fc	_	_	ns	Trigger events can be Stop, Start, Reload, Count, Capture, or Kill depending on which mode of operation is selected.
SID.TCPWM.5	TPWMEXT	Output Trigger Pulse widths	2/Fc	-	_	ns	Minimum possible width of Overflow, Underflow, and CC (Counter equals Compare value) trigger outputs
SID.TCPWM.5A	TCRES	Resolution of Counter	1/Fc	-	-	ns	Minimum time between successive counts
SID.TCPWM.5B	PWMRES	PWM Resolution	1/Fc	-	-	ns	Minimum pulse width of PWM Output
SID.TCPWM.5C	QRES	Quadrature inputs resolution	1/Fc	_	_	ns	Minimum pulse width between Quadrature phase inputs.

βC

Table 16. Fixed I²C DC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID149	I _{I2C1}	Block current consumption at 100 kHz	-	-	50	μA	
SID150	I _{I2C2}	Block current consumption at 400 kHz	_	-	135	μA	
SID151	I _{I2C3}	Block current consumption at 1 Mbps	-	-	310	μA	
SID152	I _{I2C4}	I ² C enabled in Deep Sleep mode	-	-	1.4	μA	

Table 17. Fixed I²C AC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID153	F _{I2C1}	Bit rate	-	-	1	Mbps	

LCD Direct Drive

Table 18. LCD Direct Drive DC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID154	ILCDLOW	Operating current in low power mode	_	5	-	μA	16 × 4 small segment disp. at 50 Hz
SID155	C _{LCDCAP}	LCD capacitance per segment/common driver	-	500	5000	pF	Guaranteed by Design
SID156	LCD _{OFFSET}	Long-term segment offset	_	20	-	mV	
SID157	I _{LCDOP1}	PWM Mode current. 5-V bias. 24-MHz IMO. 25 °C	-	0.6	-	mA	32 × 4 segments. 50 Hz
SID158	I _{LCDOP2}	PWM Mode current. 3.3-V bias. 24-MHz IMO. 25 °C	_	0.5	_	mA	32 × 4 segments. 50 Hz



Table 19. LCD Direct Drive AC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID159	F _{LCD}	LCD frame rate	10	50	150	Hz	

Table 20. Fixed UART DC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID160	I _{UART1}	Block current consumption at 100 Kbps	-	-	55	μA	
SID161	I _{UART2}	Block current consumption at 1000 Kbps	-	-	312	μA	

Table 21. Fixed UART AC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID162	F _{UART}	Bit rate	-	-	1	Mbps	

SPI Specifications

Table 22. Fixed SPI DC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID163	I _{SPI1}	Block current consumption at 1 Mbps	-	-	360	μA	
SID164	I _{SPI2}	Block current consumption at 4 Mbps	-	-	560	μA	
SID165	I _{SPI3}	Block current consumption at 8 Mbps	-	-	600	μA	

Table 23. Fixed SPI AC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID166	F _{SPI}	SPI operating frequency (master; 6X oversampling)	-	-	4	MHz	

Table 24. Fixed SPI Master Mode AC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID167	T _{DMO}	MOSI valid after Sclock driving edge	-	-	15	ns	
SID168	T _{DSI}	MISO valid before Sclock capturing edge. Full clock, late MISO Sampling used	20	-	-	ns	
SID169	Т _{НМО}	Previous MOSI data hold time with respect to capturing edge at Slave	0	Ι	Ι	ns	

Table 25. Fixed SPI Slave Mode AC Specifications (Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID170	Т _{DMI}	MOSI valid before Sclock capturing edge	40	-	-	ns	
SID171	T _{DSO}	MISO valid after Sclock driving edge	-	-	42+3× Tscbclk	ns	
SID171A	T _{DSO_ext}	MISO valid after Sclock driving edge in Ext. Clock mode	-	-	48	ns	
SID172	T _{HSO}	Previous MISO data hold time	0	-	-	ns	
SID172A	T _{SSELSCK}	SSEL Valid to first SCK Valid edge	100	-	_	ns	



Memory

Table 26. Flash DC Specifications

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID173	V _{PE}	Erase and program voltage	1.71	-	5.5	V	

Table 27. Flash AC Specifications

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID174	T _{ROWWRITE} ^[3]	Row (block) write time (erase and program)	_	_	20	ms	Row (block) = 128 bytes
SID175	T _{ROWERASE} ^[3]	Row erase time	-	-	13	ms	
SID176	T _{ROWPROGRAM} ^[3]	Row program time after erase	-	-	7	ms	
SID178	T _{BULKERASE} ^[3]	Bulk erase time (32 KB)	-	1	35	ms	
SID180	T _{DEVPROG} ^[3]	Total device program time	_	-	7	seconds	Guaranteed by charac- terization
SID181	F _{END}	Flash endurance	100 K	_	-	cycles	Guaranteed by charac- terization
SID182	F _{RET}	Flash retention. T _A ≤ 55 °C, 100 K P/E cycles	20	-	-	years	Guaranteed by charac- terization
SID182A		Flash retention. $T_A \le 85 \text{ °C}$, 10 K P/E cycles	10	_	_	years	Guaranteed by charac- terization
SID182B	F _{RETQ}	Flash retention. $T_A \le 105 \text{ °C}$, 10 K P/E cycles, \le three years at TA \ge 85 °C	10	Ι	20	years	Guaranteed by charac- terization

System Resources

Power-on-Reset (POR) with Brown Out

Table 28. Imprecise Power On Reset (IPOR)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID185	V _{RISEIPOR}	Rising trip voltage	0.80	_	1.45	V	Guaranteed by character- ization
SID186	V _{FALLIPOR}	Falling trip voltage	0.75	_	1.4	V	Guaranteed by character- ization
SID187	V _{IPORHYST}	Hysteresis	15	-	200	mV	Guaranteed by character- ization

Table 29. Precise Power On Reset (POR)

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID190	V _{FALLPPOR}	BOD trip voltage in active and sleep modes	1.64	-	_	V	Full functionality between 1.71 V and BOD trip voltage is guaranteed by characterization
SID192	V _{FALLDPSLP}	BOD trip voltage in Deep Sleep	1.4	-	_	V	Guaranteed by character- ization
BID55	Svdd	Maximum power supply ramp rate	_	-	67	kV/sec	

Note

It can take as much as 20 milliseconds to write to Flash. During this time the device should not be Reset, or Flash operations will be interrupted and cannot be relied on to have completed. Reset sources include the XRES pin, software resets, CPU lockup states and privilege violations, improper power supply levels, and watchdogs. Make certain that these are not inadvertently activated.



Voltage Monitors

Table 30. Voltage Monitors DC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID195	V _{LVI1}	LVI_A/D_SEL[3:0] = 0000b	1.71	1.75	1.79	V	
SID196	V _{LVI2}	LVI_A/D_SEL[3:0] = 0001b	1.76	1.80	1.85	V	
SID197	V _{LVI3}	LVI_A/D_SEL[3:0] = 0010b	1.85	1.90	1.95	V	
SID198	V _{LVI4}	LVI_A/D_SEL[3:0] = 0011b	1.95	2.00	2.05	V	
SID199	V _{LVI5}	LVI_A/D_SEL[3:0] = 0100b	2.05	2.10	2.15	V	
SID200	V _{LVI6}	LVI_A/D_SEL[3:0] = 0101b	2.15	2.20	2.26	V	
SID201	V _{LVI7}	LVI_A/D_SEL[3:0] = 0110b	2.24	2.30	2.36	V	
SID202	V _{LVI8}	LVI_A/D_SEL[3:0] = 0111b	2.34	2.40	2.46	V	
SID203	V _{LVI9}	LVI_A/D_SEL[3:0] = 1000b	2.44	2.50	2.56	V	
SID204	V _{LVI10}	LVI_A/D_SEL[3:0] = 1001b	2.54	2.60	2.67	V	
SID205	V _{LVI11}	LVI_A/D_SEL[3:0] = 1010b	2.63	2.70	2.77	V	
SID206	V _{LVI12}	LVI_A/D_SEL[3:0] = 1011b	2.73	2.80	2.87	V	
SID207	V _{LVI13}	LVI_A/D_SEL[3:0] = 1100b	2.83	2.90	2.97	V	
SID208	V _{LVI14}	LVI_A/D_SEL[3:0] = 1101b	2.93	3.00	3.08	V	
SID209	V _{LVI15}	LVI_A/D_SEL[3:0] = 1110b	3.12	3.20	3.28	V	
SID210	V _{LVI16}	LVI_A/D_SEL[3:0] = 1111b	4.39	4.50	4.61	V	
SID211	LVI_IDD	Block current	_	-	100	μA	Guaranteed by characterization

Table 31. Voltage Monitors AC Specifications

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID212	T _{MONTRIP}	Voltage monitor trip time		1	1	μs	Guaranteed by characterization

SWD Interface

Table 32. SWD Interface Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID213	F_SWDCLK1	$3.3~V \leq V_{DD} \leq 5.5~V$	-	_	14	MHz	SWDCLK ≤ 1/3 CPU clock frequency
SID214	F_SWDCLK2	$1.71 \text{ V} \leq \text{V}_{DD} \leq 3.3 \text{ V}$	_	_	7	MHz	SWDCLK ≤ 1/3 CPU clock frequency
SID215	T_SWDI_SETUP	T = 1/f SWDCLK	0.25*T	_	_	ns	Guaranteed by characterization
SID216	T_SWDI_HOLD	T = 1/f SWDCLK	0.25*T	_	_	ns	Guaranteed by characterization
SID217	T_SWDO_VALID	T = 1/f SWDCLK	-	-	0.5*T	ns	Guaranteed by characterization
SID217A	T_SWDO_HOLD	T = 1/f SWDCLK	1	-	_	ns	Guaranteed by characterization



Internal Main Oscillator

Table 33. IMO DC Specifications (Guaranteed by Design)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID218	I _{IMO1}	IMO operating current at 48 MHz	-	-	1000	μA	
SID219	I _{IMO2}	IMO operating current at 24 MHz	-	-	325	μA	
SID220	I _{IMO3}	IMO operating current at 12 MHz	-	_	225	μA	
SID221	I _{IMO4}	IMO operating current at 6 MHz	-	-	180	μA	
SID222	I _{IMO5}	IMO operating current at 3 MHz	_	_	150	μA	

Table 34. IMO AC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID223	F _{IMOTOL1}	Frequency variation from 3 to 48 MHz	-	-	±2		±3% if T _A > 85 °C and IMO frequency < 24 MHz
SID226	T _{STARTIMO}	IMO startup time	-	-	12	μs	
SID227	T _{JITRMSIMO1}	RMS Jitter at 3 MHz	-	156	-	ps	
SID228	T _{JITRMSIMO2}	RMS Jitter at 24 MHz	-	145	-	ps	
SID229	T _{JITRMSIMO3}	RMS Jitter at 48 MHz	-	139	_	ps	

Internal Low-Speed Oscillator

Table 35. ILO DC Specifications (Guaranteed by Design)

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID231	I _{ILO1}	ILO operating current at 32 kHz	_	0.3	1.05		Guaranteed by Characterization
SID233	IILOLEAK	ILO leakage current	_	2	15		Guaranteed by Design

Table 36. ILO AC Specifications

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID234	T _{STARTILO1}	ILO startup time	-	-	2	ms	Guaranteed by charac- terization
SID236	T _{ILODUTY}	ILO duty cycle	40	50	60	%	Guaranteed by charac- terization
SID237	F _{ILOTRIM1}	32 kHz trimmed frequency	15	32	50	kHz	Max ILO frequency is 70 kHz if T _A > 85 °C

Table 37. External Clock Specifications

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID305	ExtClkFreq	External Clock input Frequency	0	-	24	MHz	Guaranteed by characterization
SID306	ExtClkDuty	Duty cycle; Measured at V _{DD/2}	45	-	55	%	Guaranteed by characterization



Table 38. Block Specs

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/Conditions
SID257	T _{WS24} *	Number of wait states at 24 MHz	0	-	-		CPU execution from Flash. Guaranteed by characterization
SID260	V _{REFSAR}	Trimmed internal reference to SAR	–1	-	+1	%	Percentage of Vbg (1.024 V). Guaranteed by characterization
SID262	T _{CLKSWITCH}	Clock switching from clk1 to clk2 in clk1 periods	3	_	4	Periods	Guaranteed by design
* Tws24 is gu	uaranteed by Design	· · · · ·					



Ordering Information

The PSoC 4100 part numbers and features are listed in the following table.

							Fea	ature	s						Pa	acka	ge	
Family	NdW	Max CPU Speed (MHz)	Flash (KB)	SRAM (KB)	UDB	Op-amp (CTBm)	CapSense	Direct LCD Drive	12-bit SAR ADC	LP Comparators	TCPWM Blocks	SCB Blocks	GPIO	28-SSOP	35-WLCSP	40-QFN	44-TQFP	48-TQFP
	CY8C4124PVI-432	24	16	4	-	1	-	-	806 ksps	2	4	2	24					
	CY8C4124PVI-442	24	16	4	-	1	\checkmark		806 ksps	2	4	2	24					
	CY8C4124PVQ-432	24	16	4	-	1	-	-	806 ksps	2	4	2	24					
	CY8C4124PVQ-442	24	16	4	-	1	\checkmark		806 ksps	2	4	2	24					
	CY8C4124FNI-443	24	16	4	-	2			806 ksps	2	4	2	31					
	CY8C4124LQI-443	24	16	4	-	2	\checkmark		806 ksps	2	4	2	34					
	CY8C4124AXI-443	24	16	4	-	2			806 ksps	2	4	2	36				\checkmark	
	CY8C4124LQQ-443	24	16	4	-	2			806 ksps	2	4	2	34					
	CY8C4124AXQ-443	24	16	4	-	2			806 ksps	2	4	2	36					
	CY8C4124AZI-443	24	16	4	-	2			806 ksps	2	4	2	36					\checkmark
4100	CY8C4125AXI-473	24	32	4	-	2	-	-	806 ksps	2	4	2	36					
4	CY8C4125AXQ-473	24	32	4	-	2	-	-	806 ksps	2	4	2	36					
	CY8C4125AZI-473	24	32	4	-	2	-	-	806 ksps	2	4	2	36					
	CY8C4125PVI-482	24	32	4	-	1			806 ksps	2	4	2	24					
	CY8C4125PVQ-482	24	32	4	-	1			806 ksps	2	4	2	24					
	CY8C4125FNI-483(T)	24	32	4	-	2			806 ksps	2	4	2	31					
	CY8C4125LQI-483	24	32	4	-	2			806 ksps	2	4	2	34					
	CY8C4125AXI-483	24	32	4	-	2	\checkmark		806 ksps	2	4	2	36					
	CY8C4125LQQ-483	24	32	4	-	2			806 ksps	2	4	2	34					
	CY8C4125AXQ-483	24	32	4	-	2	\checkmark		806 ksps	2	4	2	36					
	CY8C4125AZI-483	24	32	4	-	2			806 ksps	2	4	2	36					\checkmark



Part Numbering Conventions

PSoC 4 devices follow the part numbering convention described in the following table. All fields are single-character alphanumeric (0, 1, 2, ..., 9, A,B, ..., Z) unless stated otherwise.

The part numbers are of the form CY8C4ABCDEF-XYZ where the fields are defined as follows.

Example	$\underline{CY8C} \stackrel{4}{} \stackrel{4}{} \stackrel{1}{} \stackrel{1}{\xrightarrow$
	Cypress Prefix
4: PSoC4	Architecture
1: 4100Family	Family within Architecture
2: 24 MHz	Speed Grade
5: 32 KB	Flash Capacity
AX: TQFP	Package Code
I: Industrial	Temperature Range
	Attributes Set

The Field Values are listed in the following table.

Field	Description	Values	Meaning
CY8C	Cypress Prefix		
4	Architecture	4	PSoC 4
А	Family within architecture	1	4100 Family
~		2	4200 Family
В	CPU Speed	2	24 MHz
Б	CFO Speed	4	48 MHz
С	Flash Capacity	4	16 KB
C		5	32 KB
		AX, AZ	TQFP
DE	Package Code	LQ	QFN
		PV	SSOP
		FN	WLCSP
F	Temperature Range	I	Industrial
		Q	Extended Industrial
XYZ	Attributes Code	000-999	Code of feature set in specific family



Packaging

Table 40. Package Characteristics

Parameter	Description	Conditions	Min	Тур	Max	Units
T _A	Operating ambient temperature		-40	25.00	105	°C
TJ	Operating junction temperature		-40	-	125	°C
T _{JA}	Package θ_{JA} (28-pin SSOP)		-	66.58	_	°C/Watt
T _{JA}	Package θ_{JA} (35-ball WLCSP)		-	28.00	-	°C/Watt
T _{JA}	Package θ_{JA} (40-pin QFN)		-	15.34	_	°C/Watt
T _{JA}	Package θ_{JA} (44-pin TQFP)		-	57.16	_	°C/Watt
T _{JA}	Package θ_{JA} (48-pin TQFP)		-	67.30	_	°C/Watt
T _{JC}	Package θ_{JC} (28-pin SSOP)		-	26.28	_	°C/Watt
T _{JC}	Package θ_{JC} (35-ball WLCSP)		-	00.40	_	°C/Watt
T _{JC}	Package θ_{JC} (40-pin QFN)		-	2.50	_	°C/Watt
T _{JC}	Package θ_{JC} (44-pin TQFP)		-	17.47	-	°C/Watt
T _{JC}	Package θ_{JC} (48-pin TQFP)		-	27.60	1	°C/Watt

Table 41. Solder Reflow Peak Temperature

Package	Maximum Peak Temperature	Maximum Time at Peak Temperature
28-pin SSOP	260 °C	30 seconds
35-ball WLCSP	260 °C	30 seconds
40-pin QFN	260 °C	30 seconds
44-pin TQFP	260 °C	30 seconds
48-pin TQFP	260 °C	30 seconds

Table 42. Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-2

Package	MSL
28-pin SSOP	MSL 3
35-ball WLCSP	MSL 3
40-pin QFN	MSL 3
44-pin TQFP	MSL 3
48-pin TQFP	MSL 3

PSoC 4 CAB Libraries with Schematics Symbols and PCB Footprints are on the Cypress web site at http://www.cypress.com/cad-resources/psoc-4-cad-libraries?source=search&cat=technical_documents.



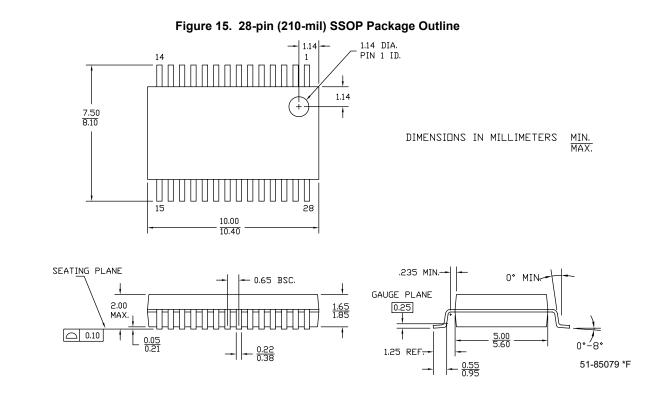
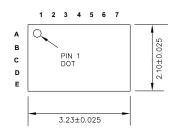


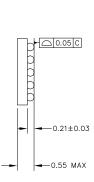
Figure 16. 35-ball WLCSP Package Outline

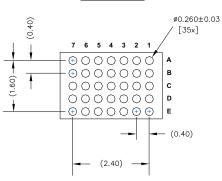




BOTTOM VIEW







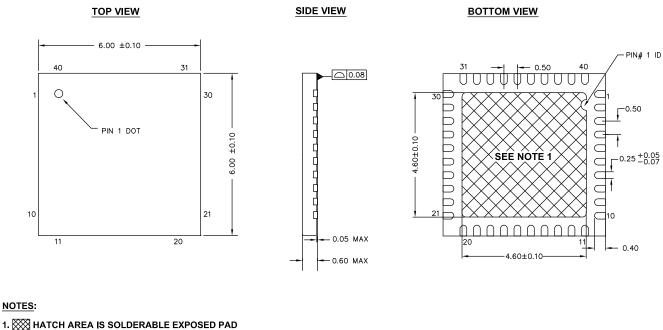
NOTES:

- 1. REFERENCE JEDEC PUBLICATION 95, DESIGN GUIDE 4.18
- 2. ALL DIMENSIONS ARE IN MILLIMETERS

001-93741 **







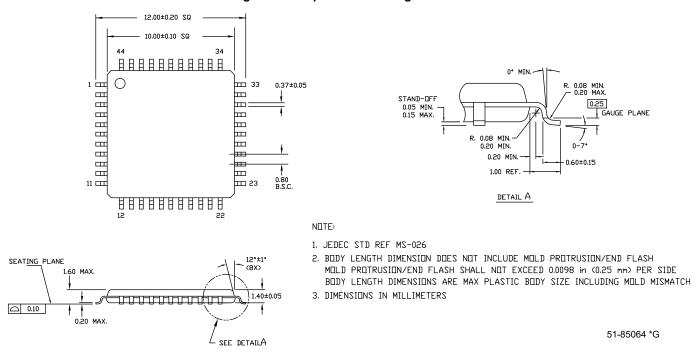
2. REFERENCE JEDEC # MO-248

3. PACKAGE WEIGHT: 68 ±2 mg

4. ALL DIMENSIONS ARE IN MILLIMETERS

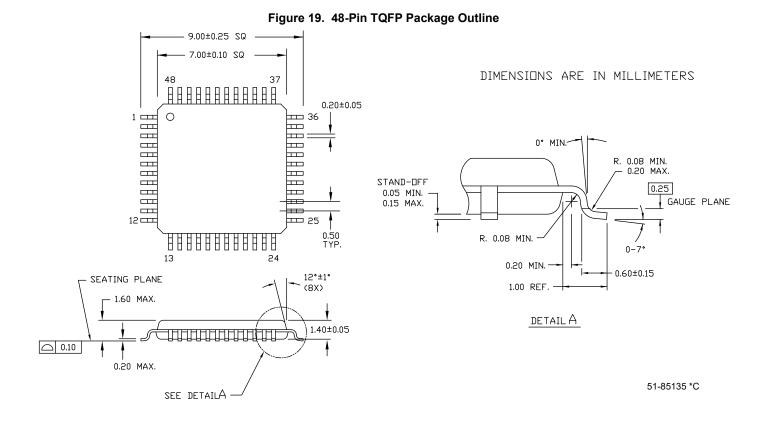
The center pad on the QFN package should be connected to ground (VSS) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floating and not connected to any other signal.

Figure 18. 44-pin TQFP Package Outline



001-80659 *A







Acronyms

Table 43. Acronyms Used in this Document

Acronym	Description
abus	analog local bus
ADC	analog-to-digital converter
AG	analog global
АНВ	AMBA (advanced microcontroller bus archi- tecture) high-performance bus, an Arm data transfer bus
ALU	arithmetic logic unit
AMUXBUS	analog multiplexer bus
API	application programming interface
APSR	application program status register
Arm [®]	advanced RISC machine, a CPU architecture
ATM	automatic thump mode
BW	bandwidth
CAN	Controller Area Network, a communications protocol
CMRR	common-mode rejection ratio
CPU	central processing unit
CRC	cyclic redundancy check, an error-checking protocol
DAC	digital-to-analog converter, see also IDAC, VDAC
DFB	digital filter block
DIO	digital input/output, GPIO with only digital capabilities, no analog. See GPIO.
DMIPS	Dhrystone million instructions per second
DMA	direct memory access, see also TD
DNL	differential nonlinearity, see also INL
DNU	do not use
DR	port write data registers
DSI	digital system interconnect
DWT	data watchpoint and trace
ECC	error correcting code
ECO	external crystal oscillator
EEPROM	electrically erasable programmable read-only memory
EMI	electromagnetic interference
EMIF	external memory interface
EOC	end of conversion
EOF	end of frame
EPSR	execution program status register
ESD	electrostatic discharge

Table 43. Acronyms Used in this Document (continued)

FIRfilFPBfilFSfLGPIOgHVIhICirIDACclIDEirI ² C, or IICIrp	embedded trace macrocell inite impulse response, see also IIR lash patch and breakpoint ull-speed general-purpose input/output, applies to a PSoC oin high-voltage interrupt, see also LVI, LVD integrated circuit current DAC, see also DAC, VDAC integrated development environment inter-Integrated Circuit, a communications protocol
FPBfliFSfLGPIOgPHVIICirIDACclIDEirI ² C, or IICIrP	lash patch and breakpoint ull-speed general-purpose input/output, applies to a PSoC bin high-voltage interrupt, see also LVI, LVD integrated circuit current DAC, see also DAC, VDAC integrated development environment inter-Integrated Circuit, a communications protocol infinite impulse response, see also FIR
FS fL GPIO g P HVI h IC ir IDAC ci IDE ir I ² C, or IIC Ir P	ull-speed general-purpose input/output, applies to a PSoC bin high-voltage interrupt, see also LVI, LVD integrated circuit current DAC, see also DAC, VDAC integrated development environment inter-Integrated Circuit, a communications protocol infinite impulse response, see also FIR
GPIO g p HVI h IC ir IDAC c IDE ir I ² C, or IIC Ir p	general-purpose input/output, applies to a PSoC nigh-voltage interrupt, see also LVI, LVD ntegrated circuit current DAC, see also DAC, VDAC ntegrated development environment nter-Integrated Circuit, a communications protocol nfinite impulse response, see also FIR
HVI h IC ir IDAC ci IDE ir I ² C, or IIC Ir	bin high-voltage interrupt, see also LVI, LVD htegrated circuit current DAC, see also DAC, VDAC htegrated development environment inter-Integrated Circuit, a communications protocol hfinite impulse response, see also FIR
IC ir IDAC cr IDE ir I ² C, or IIC Ir p	ntegrated circuit current DAC, see also DAC, VDAC ntegrated development environment nter-Integrated Circuit, a communications protocol nfinite impulse response, see also FIR
IDAC cl IDE ir I ² C, or IIC Ir	eurrent DAC, see also DAC, VDAC ntegrated development environment nter-Integrated Circuit, a communications protocol nfinite impulse response, see also FIR
IDE ir I ² C, or IIC Ir p	ntegrated development environment nter-Integrated Circuit, a communications protocol nfinite impulse response, see also FIR
I ² C, or IIC Ir	nter-Integrated Circuit, a communications protocol nfinite impulse response, see also FIR
p	nfinite impulse response, see also FIR
llR ir	
ILO ir	nternal low-speed oscillator, see also IMO
IMO ir	nternal main oscillator, see also ILO
INL ir	ntegral nonlinearity, see also DNL
I/O ir	nput/output, see also GPIO, DIO, SIO, USBIO
IPOR in	nitial power-on reset
IPSR ir	nterrupt program status register
IRQ ir	nterrupt request
ITM ir	nstrumentation trace macrocell
LCD lie	quid crystal display
	ocal Interconnect Network, a communications protocol.
LR lii	nk register
LUT lo	ookup table
LVD lo	ow-voltage detect, see also LVI
LVI lo	ow-voltage interrupt, see also HVI
LVTTL lo	ow-voltage transistor-transistor logic
MAC m	nultiply-accumulate
MCU m	nicrocontroller unit
MISO m	naster-in slave-out
NC n	no connect
NMI n	onmaskable interrupt
NRZ n	non-return-to-zero
NVIC n	nested vectored interrupt controller
NVL n	nonvolatile latch, see also WOL
opamp o	operational amplifier
PAL p	programmable array logic, see also PLD



Acronym	Description
PC	program counter
PCB	printed circuit board
PGA	programmable gain amplifier
PHUB	peripheral hub
PHY	physical layer
PICU	port interrupt control unit
PLA	programmable logic array
PLD	programmable logic device, see also PAL
PLL	phase-locked loop
PMDD	package material declaration data sheet
POR	power-on reset
PRES	precise power-on reset
PRS	pseudo random sequence
PS	port read data register
PSoC [®]	Programmable System-on-Chip™
PSRR	power supply rejection ratio
PWM	pulse-width modulator
RAM	random-access memory
RISC	reduced-instruction-set computing
RMS	root-mean-square
RTC	real-time clock
RTL	register transfer language
RTR	remote transmission request
RX	receive
SAR	successive approximation register
SC/CT	switched capacitor/continuous time
SCL	I ² C serial clock
SDA	I ² C serial data
S/H	sample and hold
SINAD	signal to noise and distortion ratio
SIO	special input/output, GPIO with advanced features. See GPIO.
SOC	start of conversion
SOF	start of frame
SPI	Serial Peripheral Interface, a communications protocol
SR	slew rate
SRAM	static random access memory
SRES	software reset
SWD	serial wire debug, a test protocol

Table 43. Acronyms Used in this Document (continued)

Acronym Description SWV single-wire viewer TD transaction descriptor, see also DMA THD total harmonic distortion TIA transimpedance amplifier TRM technical reference manual TTL transistor-transistor logic ΤХ transmit UART Universal Asynchronous Transmitter Receiver, a communications protocol UDB universal digital block USB Universal Serial Bus USBIO USB input/output, PSoC pins used to connect to a USB port VDAC voltage DAC, see also DAC, IDAC WDT watchdog timer WOL write once latch, see also NVL WRES watchdog timer reset XRES external reset I/O pin XTAL crystal

Table 43. Acronyms Used in this Document (continued)



Document Conventions

Units of Measure

Table 44. Units of Measure

Symbol	Unit of Measure		
°C	degrees Celsius		
dB	decibel		
fF	femto farad		
Hz	hertz		
KB	1024 bytes		
kbps	kilobits per second		
Khr	kilohour		
kHz	kilohertz		
kΩ	kilo ohm		
ksps	kilosamples per second		
LSB	least significant bit		
Mbps	megabits per second		
MHz	megahertz		
MΩ	mega-ohm		
Msps	megasamples per second		
μA	microampere		
μF	microfarad		
μH	microhenry		
μs	microsecond		
μV	microvolt		
μW	microwatt		
mA	milliampere		
ms	millisecond		
mV	millivolt		
nA	nanoampere		
ns	nanosecond		
nV	nanovolt		
Ω	ohm		
pF	picofarad		
ppm	parts per million		
ps	picosecond		
s	second		
sps	samples per second		
sqrtHz	square root of hertz		
V	volt		



Revision History

Revision	ECN	Orig. of Change	Submission Date	Description of Change
*В	4108562	WKA	08/29/2013	Added clarifying note about the XRES pin in the Reset section. Added a link reference to the PSoC 4 TRM. Updated the footnote in Absolute Maximum Ratings. Updated Sleep Mode IDD specs in DC Specifications. Updated Comparator DC Specifications Updated SAR ADC AC Specifications (Guaranteed by Characterization) Updated LCD Direct Drive DC Specifications (Guaranteed by Characterization) Updated the number of GPIOs in Ordering Information.
*C	4568937	WKA	11/19/2014	Added 48-pin TQFP pin and package details. Added SID308A spec details. Updated Ordering Information.
*D	4617283	WKA	01/08/2015	Corrected typo in the ordering information table. Updated 28-pin SSOP package diagram.
*E	4643655	WKA	04/29/2015	Added 35 WLCSP pinout and package detail information. Updated CSD specifications.
*F	5287114	WKA	06/09/2016	Corrected typo in the Features section. Added reference to AN90071 in the More Information section. Updated Flash section with details of flash protection modes. Added notes in the Pinouts section. Updated 40-pin QFN and 28-pin SSOP pin diagrams. Added PSoC 4 Power Supply diagram. Updated the Bypass Capacitors column in the Power Supply table. Updated values for SID32, SID34, SID38, SID269, SID270, SID271. Added SID299A. Updated Comparator Specifications. Updated TCPWM Specifications. Updated values for SID149, SID160, SID171. Updated Conditions for SID190. Added BID55. Removed Conditions for SID237. Added reference to PSoC 4 CAB Libraries with Schematics Symbols and PCB Footprints in the Packaging section.
*G	5327384	WKA	06/28/2016	Removed the capacitor connection for Pin 15 in Figure 11.
*H	5704046	GNKK	04/26/2017	Updated the Cypress logo and copyright information.
*	5738586	WKA	05/16/2017	Updated max value of SID61.
*J	5795966	WKA	07/10/2017	Changed Pin 33 name in 40-pin QFN Pinout from VDDD to VDDA to correct typo; pinout table is correct and not changed. Removed reference to swd_io[1] and swd_clk[1]. Corrected 44-TQFP Package Example.
*K	6611114	RLOS/ WKA	07/02/2019	Added AN85951 in More Information. Updated LCD Segment Drive. Updated SID55 description. Removed Conditions for SID95.



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